Van Hove Excitons and High-T<sub>c</sub> Superconductivity: V IIIC

Dynam ic Jahn-Teller E ects vs Spin-Orbit Coupling in the LTO Phase of La2 xSrxCuO4

#### R.S.Markiewicz

Physics Department and Barnett Institute, Northeastern University, Boston, MA 02115

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The possible role of the van Hove singularity (vH s) in stabilizing the low-tem perature orthorhom bic (LTO) phase transition in  $La_2 \ _xSr_xCuO_4$  (LSCO) is discussed. It is found that the vH s can drive a structural distortion in two di erent ways, either due to spin-orbit coupling or to dynam ic Jahn-Teller (JT) e ects. This paper discusses the latter e ect in som e detail. It is shown that a model H am iltonian introduced earlier to describe the coupled electron { octahedral tilt motions (bageons') has a series of phase transitions, from a high-tem perature disordered JT phase (sim ilar to the high-tem perature tetragonal phase of LSCO) to an interm ediate tem perature dynam ic JT phase, of average orthorhom bic sym metry (the LTO phase) to a low tem perature static JT phase (the low tem perature tetragonal phase). For som e param eter values, the static JT phase is absent.

#### 1. Introduction

The high-T<sub>c</sub> superconductors La<sub>2 x</sub>Ba<sub>x</sub>CuO<sub>4</sub> (LBCO) and La<sub>2 x</sub>Sr<sub>x</sub>CuO<sub>4</sub> (LSCO) have structural phase transitions from a high-tem perature tetragonal (HTT) to a low-tem perature orthorhom bic (LTO) to (in doped LBCO) a low-tem perature tetragonal (LTT) phase [1]. There is a clear association of the LTT phase with electronic properties { the transition causes a decrease in the Hall density and interferes destructively with superconductivity [2]. M oreover, the transition is complete only at a xed hole density, x 0:125 [3]. These features can be understood [4] in term s of the LTT phase splitting the degeneracy of the two van H ove singularities (vH s's) [5–7], at the X – and Y –points of the (HTT) B rillouin zone.

The role of electron-phonon coupling in the LTO phase is less clear, since transport properties are only weakly a ected by the HTT-LTO transition. W hile a uniform LTO phase could be stabilized by purely nonelectronic mechanisms, this does not explain why high-T<sub>c</sub> superconductivity appears to occur only in the orthorhom bic phase [8]. It had early been suggested that the LTO phase was a charge-density wave (CDW) phase, associated with the vHs, but Pouget, et al.[9] suggested that this interpretation was untenable, since the LTO transition does not split the degeneracy of the two vHs's. In the present paper, I show that the analysis of Pouget, et al., is incomplete: the vHs can actually drive two transitions of macroscopic LTO symmetry, to either a CDW -like phase or to a spin-density wave (SDW)-like phase.

I have recently suggested [10,11] that both LTT and LTO phases are manifestations of a novel form of band Jahn-Teller (JT) e ect [12-14], in which the degenerate electronic states are associated with the two vHs's. Thus, the LTT phase involves an essentially static band JT distortion, splitting the degeneracy of the two vHs's. The HTT and LTO phases can then both be interpreted as dynamic Jahn-Teller phases, involving tunneling between the X- and Y-point JT distortions of the LTT phase. In Ref. [10], a mean eld calculation wasmade, approximating the dynamic JT e ect by Valence bond density waves', a coherent superposition of two charge density waves (CDW 's). The resulting phase diagram reproduced the HTT ! LTO ! superconducting phases as a function of hole doping in LSCO.Ref. [11] introduced a model Ham iltonian to describe the (nonlinear) electron-phonon interaction, based on sim ilar calculations for the A 15 com pounds [15,16], and applied it to an analysis of the static JT e ect. The present paper extends these calculations to include the dynam ic JT e ect. For a single cell, the com bined electron-tilt phonon ('cageon') problem can be reduced to the problem of a particle moving am ong four potential wells, and a solution can be found in term s of M athieu's functions. The ground states are linear com binations of tilted octahedra. A dding intercell coupling leads to phase transitions with a net m acroscopic average tilt, and the accom panying static strains. A dynam ic LTO phase can be stabilized over a considerable tem perature range by entropic e ects, and the sequence HTT! LTO! LTT is naturally reproduced. A sequence of transitions is found, from a high

tem perature disordered JT phase (equivalent to the HTT phase of LSCO) to an interm ediate dynam ic JT phase, with equal tilts along the orthogonal x and y axes (an LTO phase) to a low tem perature static JT phase (LTT phase). The transition to the LTO phase is second order, while that between LTO and LTT is rst order. W ithin a certain parameter range, the LTT phase does not occur, leaving the dynam ic JT phase as the stable low -T phase.

The dynam ic JT phase o ers an interpretation of the LTO phase as having only macroscopic average orthorhom bic symmetry, with local dynam ic disorder. The question of whether the vHs can induce a transition into a uniform LTO phase is also reanalyzed, on the basis of group theory. It is found that um klapp scattering can split the vHs degeneracy, but only in the presence of spin-orbit coupling. Thus there are two vHs-based mechanisms of driving the LTO transition, in competition with each other. W hile considerably more complicated, these transitions are rem iniscent of the competition between CDW and SDW transitions in the theory of nesting instabilities in low er-dimensionalm etals.

The paper is organized as follows. Section 2 reviews the proposed role of band JT e ects in the cuprates, and their relation to ferroelectric perovskites. Section 3 introduces a modi ed form of the electron-tilt-strain coupled Ham iltonian of Ref. [11], including um klapp scattering term s. Section 4 and Appendix II show how the acoustic strains can be form ally elim inated, leading to an electron-electron interaction. Section 5 and Appendix III carefully analyze the problem of structural phase transitions in the uniform LTO phase. It is shown that, whereas um klapp scattering can in principle lead to a density wave instability, the transition is symmetry forbidden for the LTO space group, unless spin-orbit interaction is included. Section 6 analyzes the dynam ic JT state, reducing the H am iltonian to an intracell plus near neighbor coupling form, and shows the relation between the present H am iltonian and previous JT calculations. Section 7 presents the calculation of the dynam ic JT e ects at a mean-eld level, including phase diagram s of the transitions from HTT! LTO! LTT. A discussion is given in Section 8, while the interpretation of the bageon' in terms of polarons or solitons is brie y discussed in Section 9. A number of Appendices provide details of calculations: a renorm alization of the band structure to reveal separate subbands associated with each vHs (Appendix I); a group theoretical analysis of the uniform LTO phase (Appendix III); a pseudospin approximation of the electronic operators (Appendix IV); and a discussion of the solutions of the four-wellM athieu equation (Appendix V).

### 2. First-Order B and JT E ect

The JT theorem states that any orbital electronic degeneracy in a molecule is unstable: there always exists some structural distortion which lowers the energy of the molecule by lifting the degeneracy. A similar e ect can arise in a solid, either for a local impurity or for a collective JT e ect in the crystal as a whole. M any perovskites and related structures have a phase transition to either a ferroelectric or antiferrodistortive phase, which can be interpreted as a collective JT e ect [13].

In the cuprates, the structural transitions are complicated, involving tilts of the oxygen octahedra (optical phonons), static strains and acoustic phonons, as well as electron-phonon coupling. Moreover, the coupling of the optical phonons to both the strains and the electrons is nonlinear. A model for these interactions was introduced in Ref. [11]. There, it was suggested that both the LTO and LTT phase transitions were driven by the diverging electronic susceptibility associated with the vH s. Indeed, these transitions can be considered as a generalization to two dimensitions of the Peierls instability.

The LTT phase transition can be thought of as a vH s-JT transition. The presence of two vH s's, at the X and Y points of the B rillouin zone, provides the electronic degeneracy, while the tilting of the octahedra split this degeneracy, as in a traditional (band) JT e ect. Interpretation of the LTO phase is more complicated, since the associated octahedral tilting leaves the vH s's degenerate, essentially because the two in-plane Cu-O distances are equal in the LTO phase [9]. How ever, this rules out only the sim plest model of the CDW /SDW phase. In the present paper, I show that there rem ain a large num ber of potential ground states, stabilized by (partial) splitting of the vH s degeneracy. I suggest that two of these states m ay be actually realized in LSCO: a static, SDW -like phase near half lling (Section 5), and a dynam ic, CDW -like phase in the doped m aterial (Section 7).

The di erence between the two transitions can be understood from Fig. 1, which illustrates two di erent means of splitting the vHs peak in the dos. This Figure illustrates the Ferm i surfaces corresponding to the LTT phase (Fig. 1a) and to a possible LTO phase (Fig. 1b). The Ferm i surfaces at the vHs have been

distorted from square by including a nite oxygen-oxygen hopping energy,  $t_{00}$  in the dispersion relations.

Figure 1a shows Ferm i surfaces of the LTT phase for two di erent dopings { the Ferm i level coincides with the X -point vHs at one doping, and with the Y -point vHs at the other. In the LTT phase, the two Cu-O distances are no longer degenerate, so the Cu-O hopping parameter becomes anisotropic, splitting the vHs degeneracy [4]. (Due to the unusual layering, this compound has a complicated c-axis dispersion: the roles of X -point and Y -point vHs's are interchanged on every other layer. It m ight be thought that such a large c-axis dispersion would wash out the e ects of the vHs, but in fact, it is a consequence of the vHs splitting in the LTT phase.) In the dynam icm odel of the LTO phase, the symm etry ism icroscopically LTT, thereby locally splitting the vHs degeneracy, but with a macroscopic orthorhom bic strain.

This is to be contrasted with the situation in the uniform LTO phase, Fig. 1b. The LTO transition doubles the unit cell volume, thereby reducing the B rillouin zone volume by the same factor, and introducing a two-fold degeneracy in all bands. Unklapp scattering can in principle lift the degeneracy of the two bands, so that their respective vH s's coincide with the Ferm i level at two di erent dopings, as illustrated in Fig. 1b. Note that in Fig. 1a, the Ferm i surface of a single band is illustrated at two di erent dopings, whereas Fig. 1b shows the Ferm i surfaces of two di erent bands at a single doping level. Note further that, within either band in Fig. 1b, the two vH s's remain degenerate[9]. The splitting of Fig. 1b can be used, for instance, to describe interlayer coupling in the cuprates. In this case, the two bands' would correspond to the Ferm i surfaces at  $k_z = 0$ ; =c, which are degenerate when interlayer hopping is neglected. However, interlayer coupling is weak in these materials, and for simplicity it will be neglected.

O fm ore interest is the possibility of introducing a gap by coherently coupling excitations between the two vH s's. Such in-plane coupling was introduced by Schulz[17], and is very similar to that introduced in the ux phase[18] of a doped antiferrom agnet. However, a group theoretical analysis rules out such a possibility for a CDW -like excitation: there is a two-fold degeneracy of electronic levels on the Brillouin zone face, which can only be split by spin-orbit coupling. This suggests that vH s splitting can lead to a uniform LTO phase only in the presence of antiferrom agnetic order { i.e., close to half lling. Away from half lling, the m agnetic state becomes inhom ogeneous[19]. Hence, in the doping range associated with superconductivity, there is competition between a disordered m agnetic state and a dynamic JT state. Both phases will be described in greater detail below.

It seems likely that dynamic e ects are important in the higher  $T_c$  phases, and that the sequence HTT! LTO! LTT may parallel the sequence of structural transitions in the perovskite, BaTiO<sub>3</sub>[20]. Here, four successive phase transitions are observed as temperature is lowered, from cubic to tetragonal to orthorhom bic to rhom bohedral. The rhom bohedral phase can be identified as a static JT phase, in which the T i are all distorted along one of the eight octahedral directions. The higher T phases correspond to dynamic JT phases, in which the T i tunnels between successively two, four, or all eight octahedral sites. In particular, the 'tubic' phase is not m icroscopically of cubic symmetry, but is a disordered phase with m icroscopic rhom bohedral and m acroscopic average cubic symmetry. A similar model can apply to LSCO, with a disordered or dynamic JT phase consisting of a random tilting of the oxygen octahedra about each Cu, with tunneling between all four allowed tilts in the HTT phase, between two in the LTO phase, and with only one tilt (static JT) in the LTT phase. Section 7 shows that such a sequence of phase transitions naturally follows from the H am iltonian introduced [11] to describe this system.

Recent calculations [11,21] have con m ed the close relation between the ferroelectric perovskites and the superconducting cuprates. In [11] it was pointed out that electron-phonon interaction can lead to a structural instability (negative harm onic phonon frequency) even in a led band, as long as the Ferm i level fell between the bonding and antibonding bands associated with hybridizing atom s. This is clearly the case in  $La_2CuO_4$ , and Cohen [21] has shown that T i-O hybridization is essential for ferroelectricity in B aT iO<sub>3</sub> and PbT iO<sub>3</sub>.

### 3. Theory of the Structural Transition

The present calculations are based on the nonlinear electron-phonon H am iltonian introduced in R ef. [11]. For convenience, when referring to equations from R efferences [10] or [11], I will pre x them with a letter A or B respectively (i.e., Eq. 10 of R ef. [11] will be referred to as Eq. B10, etc.).

It is convenient to rew rite the Ham iltonian of Ref. [11] as

$$H = H_{str} + H_{ph} + H_{e} + H_{ps} + H_{es} + H_{ep}:$$
(1)

The various term s of Eq. 1 refer to

static strains and acoustic phonons

$$H_{str} = \frac{1}{2M} \bigvee_{q}^{X} P(\textbf{;}q)P(\textbf{;}q) + \bigvee_{q}^{X} C_{+}e_{+}(\textbf{q})e_{+}(\textbf{q}) + C_{-}e_{-}(\textbf{q})e_{-}(\textbf{q}) + 2C_{66}e_{12}(\textbf{q})e_{12}(\textbf{q}) : (2)$$

Here,  $e_{ij}$  is the usual strain tensor, the elastic constants are  $C_{ij}$  [6], and  $e = (e_{11} e_{22})=2$ ,  $C = C_{11} C_{22}$ . The strain tensor includes both static and dynamic parts (both strains and acoustic phonons), and the P (;q)'s are the momenta associated with the acoustic phonons. In the HTT phase, there may be static strains due to (anisotropic) therm alexpansion:  $e_{11} \notin 0$ . A non-vanishing  $e_{12}$  arises in the LTO phase. In the HTT and LTO phases,  $e_{11} = e_{22}$ . This is also true in the LTT phase of LBCO, due to interlayer strains[11], but need not be true in general. To simplify the present calculations, I will apply them to a 'single layer' m odel of LBCO, for which  $e \notin 0$  in the LTT phase.

## electronic m odes

In the vH s m odel, there is a single, hybridized Cu-O band at the Ferm i level. However, as discussed in Section 2, it is convenient to treat the two vH s as independent, since they have opposite responses to e strains. Hence, the carriers will be assumed to belong to group 1 or 2, depending on whether they are nearer the X - or Y -point vH s, respectively. In Appendix I, this assumption will be justiled by calculating such subbands from a renormalized m icroscopic H am iltonian of the hybridized Cu-O planes. The electronic energy may be written as

$$H_{e} = \int_{ik}^{\Lambda} E_{i}(k) a_{ik}^{\gamma} a_{ik}; \qquad (3)$$

with i=1,2. It is convenient to de ne the integrated density of states for each vH s as

$$_{ij}(q) = \bigvee_{k}^{X} < a_{ik}^{Y} a_{j;k+q} > ;$$
(4a)

$$(q) = {}_{11}(q) {}_{22}(q):$$
 (4b)

In the HTT and LTO phases,  $_{11} = _{22}$ , whereas they are unequal (the JT splitting) in the LTT phase. The term involving  $_{12}$ , which is in general allowed by symmetry, corresponds to inter-vHs coupling. This term is related to um klapp scattering between the two vHs, and can act as a competing mechanism to the dynamic JT e ect. In Section 5 it will be shown that such a term could drive a structural transition within a purely orthorhom bic phase. However, it will further be shown that  $_{12}$  is symmetry forbidden at the vHs in the uniform LTO phase, in the absence of spin-orbit coupling.

In the present paper, only intraband inter-vH s coupling will be considered, with  $_{12}$  coupling the vH s's separated by wave vector  $Q_0 = (=a; =a)$ , as in Refs. [10,11]. It should, however, be noted that similar considerations could be applied to interlayer coupling, as discussed in Section 2 (Fig. 1b).

#### optical (tilting) m odes

T illing of the oxygen octahedra can be described in term s of (pseudo)rotation operators, for rotations about the in-plane x- and y-axes[11,22], with  $R_x$  and  $R_y$  being the magnitude of the tilt. To simplify the resulting expressions, it is convenient to de ne som e auxilliary pair tilting operators. Thus,

$$R_{ij}(q;q^{0}) = R_{i}(q+q^{0})R_{j}(q-q^{0});$$
 (5a)

$$R_{ij}^{(1)}(q) = \sum_{q=0}^{X} R_{ij}(q;q^{0});$$
(5b)

$$R_{ii}^{(2)}(q) = \begin{cases} X \\ R_{ii}(q;q^{0}) \\ q^{0};j \end{cases} (\cos(q_{j}a) \cos(q_{j}^{0}a));$$
(5c)

...

with ij = 1 when  $i \neq j$ , ij = 1; 2. In this case, H<sub>ph</sub> becomes[11]

$$H_{ph} = \frac{1}{2} X X K (q)P (q)P (q) + t_0^2 (q) (R_{11} (0;q) + R_{22} (0;q))$$

$$+ \frac{0}{4} \mathbb{R}_{11}^{(2)} (q) \mathbb{R}_{11}^{(2)} (q) + \mathbb{R}_{22}^{(2)} (q) \mathbb{R}_{22}^{(2)} (q)]$$

$$+ \frac{a}{0} \mathbb{R}_{11}^{(1)} (q) \mathbb{R}_{11}^{(1)} (q) + \mathbb{R}_{22}^{(1)} (q) \mathbb{R}_{22}^{(1)} (q)] + \frac{1}{2} \mathbb{R}_{11}^{(1)} (q) \mathbb{R}_{22}^{(1)} (q); \qquad (5d)$$

where P is the momentum conjugate to R, runs over 1 and 2 (x and y), and K is de ned in Eq. B17a. electron-strain coupling The strain-electronic interaction is

$$H_{es} = \int_{q}^{X} G_{+} e_{+} (q)_{+} (q) + G_{e} (q)_{+} (q) + 2G_{66}e_{12} (q)_{12} (q) :$$
(6)

with  $G = G_{11}$   $G_{22}$ . The term in  $G_{66}$  couples the orthorhom bic shear strain  $e_{12}$  of the LTO phase to the um klapp term ,  $< _{12} >$ .

strain-tilt coupling

The optical phonon coupling with strain (H  $_{\rm ps}$ ) can be written

$$H_{ps} = \sum_{q}^{X} F_{+} e_{+} (q) R_{+}^{(3)} (\frac{q}{2}) + F e (q) R_{-}^{(3)} (\frac{q}{2}) + F_{66} e_{12} (q) R_{0}^{(3)} (\frac{q}{2}) :$$
(7a)

Here, I have introduced the com bination

$$R^{(3)}(q) = \cos(q_{y}a)R^{(2)}_{11}(q) \quad \cos(q_{x}a)R^{(2)}_{22}(q);$$
(7b)

and

$$R_{0}^{(3)}(\mathbf{q}) = \sum_{q^{0}}^{X} R_{12}(\mathbf{q};\mathbf{q}^{0}) (1 \quad \cos((\mathbf{q}_{y} + \mathbf{q}_{y}^{0})\mathbf{a})) (1 \quad \cos(\mathbf{q}_{x} \quad \mathbf{q}_{x}^{0})\mathbf{a})):$$
(7c)

These equations reduce to the corresponding expressions in Ref. [11] when q = 0. In that reference, the H am iltonian was evaluated only for wave numbers near the soft mode, q = 0,  $q^0$  at one of the vH s (either (0; =a) or (=a;0)).

electron-tilt coupling T he optical phonon coupling with electrons  $(H_{ep})$  can be written

$$H_{ep} = \int_{q}^{X} \sim_{+}^{e} + (q)R_{+}^{(3)}(\frac{q}{2}) + \sim^{e} (q)R_{-}^{(3)}(\frac{q}{2}) + \sim^{e} 12(q)R_{0}^{(3)}(\frac{q}{2}) :$$
(8)

In the notation of Ref. [11],  $\sim^{e} = (e^{e})=2m$ ,  $\sim^{e} = e^{e}=2m$ . This is a nonlinear electron-phonon coupling, sim ilar to term swhich have recently been introduced [23].

All of the above terms involve a sum over q. In an RPA approximation, the various q's are decoupled. The soft mode is associated with q = 0, so in many applications the non-0 q-terms may be neglected (e.g., only terms in R<sup>(3)</sup>(0) remain). Moreover, except for the tilt term, Eq. 5d, the Ham iltonian separates into three parts, involving (e<sub>+</sub>, +, R<sup>(3)</sup><sub>+</sub>), (e, , R<sup>(3)</sup>), and (e<sub>12</sub>,  $_{12}$ , R<sup>(3)</sup><sub>0</sub>). In Appendix II, a toy model is introduced which allows a similar separation of the tilt term s, Eq. 5d, as well.

The three groups of terms play very di erent roles in the structural transitions, particularly in the presence of dynam ic JT e ects. At high tem peratures, corresponding to the HTT phase, there are local tilts of the octahedra, but with no long-range correlations. In this case,  $\langle R_x^2 + R_y^2 \rangle \notin 0$ , while  $\langle R_x \rangle = \langle R_y \rangle = 0$ . Hence, the rst set of terms controls short range order, and is non-vanishing in the HTT phase. These terms s will have a weak tem perature dependence at lower tem peratures, which can be neglected to simplify the study of the dynam ics { i.e., the rst group of terms contributes a constant value to the H am iltonian and can be neglected.

The second group of terms is nonzero in the LTT phase, and the last in the LTO phase. Hence, these terms describe the dynamic competition between the LTT and LTO phases.

### 4. E lim inating the Strain and A coustic Phonon M odes

The elastic strain tensor  $e_{ij}$  has static components associated with static strains and time-dependent components associated with acoustic phonons[11,22]. However, in studying structural phase transitions, it is often convenient to treat the strains separately from the acoustic phonons. For instance, condensation of an optical mode may induce a static strain. Consider a line of corner-shared octahedra: if the interatom ic distances remain xed, a static, antiferrodistortive tilt distortion of the octahedra will reduce the overall length of the chain. This seems to be the case in the cuprates: the octahedral strain in the LTO phase is found to be a secondary order parameter, proportional to the square of the octahedral tilt angle[24]. These strains may be form ally decoupled from the problem, following standard practice[12–14], by de ning

$$\mathbf{e}_{\mathrm{p}} = \mathbf{e}_{\mathrm{p}} + \mathbf{p}; \tag{9}$$

(p = ;12) and chosing  $_{p}$  in such a way as to elim inate the cross term s between  $e_{p}$  and  $_{p}$ ;  $R_{i}R_{j}$ . The procedure is carried out in detail in Appendix II, but for illustrative purposes, a simpler calculation is given here. Consider the sub-H am iltonian

$$H^{0} = 2C_{66}e_{12}^{2} + 2G_{66}e_{12} _{12}$$
(10a)

Taking  $_{12} = G_{66} _{12} = 2C_{66}$  transforms the Ham iltonian to

$$H^{0} = 2C_{66} \mathbf{e}_{12}^{2} \quad \frac{J_{12}}{2} \quad \frac{2}{12};$$
(10b)

with  $J_{12} = G_{66}^2 = C_{66}$ . Thus, the phonon motion is form ally decoupled from the electron, leading to an attractive interaction between electrons. However, an electronic phase transition is accompanied by a static distortion: since when  $\langle e_{12} \rangle = 0$ , then

$$< e_{12} > = \frac{G_{66}}{2C_{66}} < {}_{12} > :$$
 (11)

The separation of charge and phonon variables is not complete ( $e_{12}$  does not commute with  $_{12}$ ), but it has been argued that the additional complications of noncommutivity are unimportant (see discussion in Ref. [14], pp. 24-25, and references cited therein). The resulting attractive interaction between electrons is very similar to that found in the density wave calculation [10,25], Eq. 2.8 of Ref. [25], which, in the present notation, becomes

$$V_{kq} = \frac{G_{66}^2 h!_q = 2}{(E_k - E_{k+q})^2 (h!_q)^2} ! \frac{G_{66}^2}{2h!_q};$$
(12)

Equations 11 and 12 di er only in the denom inator, with one equation containing C<sub>66</sub>, the other h!<sub>q</sub>. This substitution arises quite naturally. In Eq. 2, the term  $e_{12}$  (q) includes both static strains and acoustic phonons. If the phonons only were included, the term  $2C_{66}e_{12}$  (q) $e_{12}$  (q) !  $c_q^v c_q$  (h!<sub>q</sub> + 1=2), where the  $c_q$  are phonon operators. E limination of the electron-phonon coupling as above would then lead to an elective electron-electron coupling, Eq. 11 with  $C_{66}$  ! h!<sub>q</sub>.

In Appendix II, a toy model H am iltonian is introduced, which allows the optical phonon coupling to be eliminated in the same fashion, leaving a purely electronic H am iltonian with an attractive electronelectron interaction. There is also the decoupled phonon H am iltonian, which splits into two parts: (1) an acoustic phonon part which, being purely harm onic, can be neglected; (2) an optical phonon part, which remains anharm onic, but with renorm alized coe cients.

# 5. Uniform LTO Phase

Before analyzing the dynam ic JT phase, it is in portant to reexam ine the question of whether a structural transition from the HTT phase to a uniform phase of microscopic LTO symmetry could somehow be driven

by the vHs.At rst sight, it would appear that this question has already been answered in the negative by the work of Pouget, et al.[9]. However, their analysis did not consider all possible mechanisms for driving a structural instability.

E lectron-phonon interaction can lead to a structural instability if the structural distortion drives a signi cant density of electronic states below the Ferm i level, as in the one-dimensional CDW problem, due to Ferm i surface nesting. In the presence of two degenerate vHs, there are two di erent ways in which a large dos could be shifted below the Ferm i level. First, the structural distortion could split the degeneracy of the two vHs, so that one vHs is shifted below the Ferm i level, the other above. This is clearly what happens in the LTT phase of LBCO, Fig. 1a, and is the basis for the dynam ic JT model of the LTO phase, discussed in Sections 6 and 7. As shown by Pouget, et al.[9], the vHs degeneracy is not lifted in the uniform LTO phase.

However, there is an alternate mechanism for structural distortion, which could in principle provide a static model for a uniform LTO phase. In this mechanism, um klapp scattering couples electronic states on degenerate bands of the Ferm i surface, Fig. 1b, leading to coherent superpositions of the two states with a corresponding gap between the superposed states. In the LTO phase, there is no splitting of the vH s (Fig. 1b), but the two vH s are now at symmetry-equivalent points of the Brillouin zone, thereby allowing inter-vH s um klapp scattering. By introducing a gap at the vH s, this mechanism can again stabilize a lattice instability. In the Equations, 1-8, this inter-vH s coherence corresponds to a nite expectation value for  $_{12}$ , and the um klapp scattering to the G  $_{66}$  and  $\sim^{e}$  term s. For the calculations of this section, it will be assumed that the two vH s's are separated by Q  $_{0}$  = ( =a; =a), although, as discussed below Eq. 4, other Q -vectors are possible.

The present section is arranged as follows. In Section 5a, the um klapp mechanism is discussed, and it is shown that it is likely to be weak in doped LSCO: it is symmetry-forbidden in the absence of spin-orbit interaction. Section 5b will further demonstrate that the static model cannot explain the sequence of transitions from HTT to LTO to LTT in terms of competition between  $_{12}$  and  $_{12}$  and a single and a degree on the sequence of phase

# 5a. Interpretation of $_{12}$

The signi cance of the term  $_{12}$ , Eq. 4, can be clari ed by recalling the usual manner in which gaps in the electronic spectrum open at a Brillouin zone boundary [26]. Um klapp scattering mixes states at k and k + Q. Thus, the electron at the zone boundary k = Q = 2 mixes with that at k = -Q = 2,

$$= a_{+} c_{Q=2}^{y} + a c_{Q=2}^{y};$$
(13a)

with the a's determ ined by the eigenvalue equation

$$(E_{0=2} E)a_{+} + U_{0}a = 0;$$
 (13b)

$$U_{0}a_{+} + (E_{0=2} E)a = 0;$$
 (13c)

where  $U_Q$  is a measure of the coupling. Now in the LTO phase, the X and Y point vHs's are separated by a reciprocal lattice vector, so a similar coupling can arise. In the present form alism, this coupling arises by rederiving Eq. B24 in the presence of the term in  $e_{12}$  12. Neglecting uctuating quantities, Eq. B24 becomes

$$i\frac{\theta}{\theta+}a_{nk} = E_n(k)a_{nk} + E_{a_{mk}mn}; \qquad (14)$$

$$E'_{1}(k) = E_{1}(k) + G e + \sim^{e} R^{2}$$
; (15a)

$$\vec{E}_{2}(k) = E_{2}(k)$$
 G e  $\sim^{e} R^{2}$ ; (15b)

$$E'(k) = 2G_{66}e_{12} + \sim^{e}R_{1}R_{2}$$
: (15c)

E quation 14 shows that, because of the  $_{12}$ -term, carriers from the two vH s interact with each other, in the presence of an orthorhom bic strain ( $e_{12} \notin 0$  or  $R_1 = R_2 \notin 0$ ). In this case, the correct eigenstates can be found by the B ogoliubov construction. Dening

$$a_{1k} = \cos()q_k + \sin()q_k;$$
 (16a)

$$a_{2k} = \sin()q_k + \cos()q_k;$$
 (16b)

then the equations of m otion for the  $c_{ik}$  's are decoupled if

$$\tan (2) = \frac{2\vec{E}(k)}{\vec{E}_{2}(k) - \vec{E}_{1}(k)};$$
(17a)

and the eigenenergies become

$$E = E'_{+} \qquad E'^{2} + E'^{2}; \qquad (17b)$$

with  $E' = (E'_1 E'_2)=2$ . The term  $E'_+$  may be neglected in Eq. 17b, since any term which shifts both electronic bands equally will be compensated by a corresponding shift of the Ferm i level. Thus, when a static orthorhom bic strain appears (<  $e_{12} > 6$  0), a gap 2E' arises in the electron spectrum, driving the high density of states associated with the vH s below the Ferm i level.

In fact, however, the term s in  $_{12}$  must vanish identically in a uniform LTO phase, in the absence of spin-orbit interaction. This follows from the sym metry group B m ab of the LTO phase, and can be considered as a generalization of Pouget, et al.'s result[9]. Because the lattice contains glide planes, the eigenfunctions must be two-fold degenerate on one face of the B rillouin zone, so no gap ( $_{12} \notin 0$ ) can arise. However, spin-orbit interaction splits most of the residual degeneracy, allowing a gap to open at the vH s. The group theoretical arguments are discussed in more detail in Appendix III, and the elect of such spin-orbit coupling on the vH s will be discussed in Section 8.

#### 5b. M ean Field Transition in Electronic H am iltonian

The above form alism can also be used to study the competition between static distortions of LTO vs LTT symmetry. This is most clearly seen by analyzing the electron-electron coupling terms in Eq. 10b. To simplify this analysis, it is convenient to temporarily neglect the tilt coupling and study just the electronic Ham iltonian. A lternately, the toy Ham iltonian of Appendix II can be used to form ally eliminate the tilt-electron coupling. From Appendix II the electronic Ham iltonian is found to be

$$H = \frac{1}{2} X \qquad (q) \qquad (q) + J_{0 \ 12} (q) \qquad (q) + J_{12} (q) \qquad (18)$$

with the coupling constants,  $J_i$ , de ned in Eq. II6. A term in + has been neglected in Eq. 18. From charge conservation, + (0) must be a xed constant, which can be set equal to zero by adjusting the Ferm i level. D ue to the logarithm ic divergence of the electronic susceptibility at the vH s, the dom inant singularity (soft m ode) corresponds to q = 0, and at the RPA level of approximation, this is the only mode which need be discussed.

The mean eld solution can be found easily, as in Section 5a and Ref. [10]. The mean eld Ham iltonian becomes

$$H_{MF}^{e} = \sum_{k}^{K} E_{k} (a_{1k}^{y} a_{1k} + a_{2k}^{y} a_{2k}) D (a_{1k}^{y} a_{1k} - a_{2k}^{y} a_{2k}) D_{0} (a_{1k}^{y} a_{2k} + a_{2k}^{y} a_{1k});$$
(19a)

w ith

$$D = \frac{J}{2} < (0) > ;$$
 (19b)

$$D_0 = \frac{J_0}{2} < _{12}(0) > :$$
 (19c)

 $H_{MF}^{e}$  can be diagonalized as in Eqs. 16, 17, yielding eigenvalues

$$E_{k} = E_{k} \quad D; \qquad (20)$$

with  $D^2 = D^2 + D_0^2$ . The self-consistency conditions, Eqs. 19b, c, yield equations for the two gaps

$$D = \frac{J D}{2D} \sum_{k}^{X} f(E_{k+}) f(E_{k}); \qquad (21a)$$

$$D_{0} = \frac{J_{0}D_{0}}{2D} \int_{k}^{k} f(E_{k+}) f(E_{k-}); \qquad (21b)$$

where  $f(E) = 1 = (\exp((E - E_F) = k_B T) + 1)$ . Except in the special case  $J = J_0$ , Eqs. 21a,b cannot simultaneously have nonvanishing solutions. Instead, the solution with the larger value of  $J_i$  prevails. This makes good physical sense: the two transitions, LTO and LTT, are both driven by the same dos peak. W hichever phase is stabilized rst uses up the available dos, and prevents the other from occurring.

In this case, the calculation m ay be simplied by ignoring terms of the non-condensing symmetry. This was in elect what was done in Refs. [10] and [11]. In Ref. [10], only the LTO solution appeared, while the calculations of Ref. [11] neglected terms involving  $_{12}$ , and predominantly described the LTT phase. It should be particularly noted that the present calculation has reproduced the BCS-like calculations of Ref. [10], but starting from the more microscopic Ham iltonian of Ref. [11], thereby explicitly displaying the close connection between the two works.

To compare with the results of Ref. [10], assume the LTO phase is favored, i.e.,  $J_0 > J$ . Then D = 0, and the gap  $D = D_0$  is given by the solution of

$$1 = \frac{J_0}{2D}^2 dE N (E) f (E D) f (E + D) ; \qquad (22)$$

For a logarithm ic dos,

N (E) = 
$$\frac{1}{B} \ln \frac{B}{2E}$$
; (23)

the zero tem perature gap is

$$D(0) = \frac{eB}{2}e^{B=J_0}:$$
 (24)

This should be compared to Eq. 14 of Ref. [26]. Figure 2 illustrates the temperature dependence of the gap, found by solving Eq. 22-23 numerically. Note that, based on Eq. 11, there will be a nonvanishing orthorhom bic strain in the LTO phase,  $\langle e_{12} \rangle / \langle 1_2 \rangle$ . Indeed, the present solution is similar to that found in Ref. [11], M odel 2, except that inclusion of um klapp processes drives the large vH s dos below the Ferm i level.

This section has explored the role of the term  $_{12}$  in stabilizing a static LTO phase. However, symmetry arguments suggest that such terms are small in the absence of spin-orbit coupling. Hence, in Sections 6 and 7, the opposite limit will be explored. Terms in  $_{12}$  will form ally be retained in the Ham iltonian, but I will attempt to determ ine under what circum stances an LTO -type phase might arise when the  $_{12}$  terms are small or vanishing. It will be shown that the LTO phase can be interpreted as a dynamic JT phase.

# 6. D ynam ic JT H am iltonian

## 6a. Real-Space H am iltonian: Intracell and Intercell C oupling

This section will present a more accurate treatment of the combined electron-optical phonon H am iltonian, following a conventional treatment of the dynamic JT e ect. It is convenient to rst transform the H am iltonian, Eq. 1, back into real space:

$$H = \frac{X}{\frac{1}{2}} - \frac{0}{4} \left[ \frac{R_1(I) - R_1(I + a\dot{\gamma})}{2} \right]^4 + \frac{R_2(I) - R_2(I + a\dot{\gamma})}{2} + \frac{a}{2} R_1^4(I) + R_2^4(I) \right] + \frac{2}{2} R_1^2(I) R_2^2(I)$$

$$+ (\sim_{+}^{e} + (1) + F_{+} e_{+} (1)) [(\frac{R_{1}(1) - R_{1}(1 + a\hat{y})}{2})^{2} + (\frac{R_{2}(1) - R_{2}(1 + a\hat{x})}{2})^{2}]$$

$$+ (\sim^{e} (1) + F_{-} e_{-} (1)) [(\frac{R_{1}(1) - R_{1}(1 + a\hat{y})}{2})^{2} - (\frac{R_{2}(1) - R_{2}(1 + a\hat{x})}{2})^{2}]$$

$$+ (\frac{\sim^{e} - 12(1) + F_{-} e_{-} e_{-} (1)}{4})^{X} R_{1}(1) - R_{1}(1 + \hat{y}a)]R_{2}(1) - R_{2}(1 + \hat{y}a)]$$

$$+ \frac{L_{0}^{2}}{2}(R_{1}(1)^{2} + R_{2}(1)^{2}) + C_{+} e_{+}^{2}(1) + C_{-} e^{2}(1) + 2C_{-} e_{-}^{2}e_{-}^{2}(1)$$

$$+ G_{+} e_{+}(1) + (1) + G_{-} e_{-}(1) - (1) + 2G_{-} e_{-}(1) - 12(1);$$

$$(25)$$

where and  $^{0}$  are sum m ed over 1 and

$$(I) = a_{11}^{y} a_{11} \quad a_{21}^{y} a_{21};$$
(26)

with a similar expression for  $_{12}$ . To form the full H am iltonian, Eq. 1, the electronic energy, Eq. 3, and the kinetic energy term s of Eqs. 2 and 5d must be added to Eq. 25. M oreover, a possible q-dependence of  $k_0$  has been neglected. E lim inating the strain term s from Eq. 25, as in Appendix II, yields

$$H = H_{str}^{*} + \frac{X}{l_{str}} - \frac{0}{4} \left[ \left( \frac{R_{1}(I) - R_{1}(I + a\hat{y})}{2} \right)^{4} + \left( \frac{R_{2}(I) - R_{2}(I + a\hat{x})}{2} \right)^{4} \right] + \frac{0}{2} \left[ R_{1}^{4}(I) + R_{2}^{4}(I) \right] + \frac{2}{2} R_{1}^{2}(I) R_{2}^{2}(I) + \frac{2}{2} R_{1}^{2}(I) + \frac{2}{2} R_{1}^{2}(I) R_{2}^{2}(I) + \frac$$

where  $_{0}^{0} = _{0} F_{+}^{2} = C_{+} F^{2} = C_{+} e^{e^{0}} = e^{e} G F = 4C$ ,  $e^{e^{0}} = e^{e} G_{66}F_{66} = 2C_{66}$ ,  $J^{0} = G^{2} = 2C$ , and  $J_{0}^{0} = G_{66}^{2} = C_{66}$ ;  $H_{str}$  is a quadratic pseudostrain H am iltonian (Eq. IIa1) decoupled from the remaining terms and of no further interest; and

$$H = \frac{1}{32} X_{0+} [(R_1 (I) R_1 (I + a\dot{y}))^2 (R_1 (I) R_1 (I - a\dot{y}))^2 + (R_2 (I) R_2 (I + a\dot{x}))^2 (R_2 (I) R_2 (I - a\dot{x}))^2]$$

$$+ {}_0 [(R_1 (I) R_1 (I + a\dot{y}))^2 + (R_1 (I) R_1 (I - a\dot{y}))^2] [(R_2 (I) R_2 (I + a\dot{x}))^2 + (R_2 (I) R_2 (I - a\dot{x}))^2]$$

$$+ {}_{00} X_{R_1} (I) R_1 (I + \dot{y}a) [R_2 (I) R_2 (I + \dot{y}a)]^2; \qquad (27b)$$

with  $_{0}$  = F  $_{+}^{2}$  =C  $_{+}$  F  $^{2}$  =C ,  $_{00}$  = F  $_{66}^{2}$  =8C  $_{66}$  .

The role of the strain forces can be determined by comparing Eqs. 25 and 27. In addition to the electron-electron interaction terms, the strain has introduced longer-range tilt-tilt interactions. All of the terms of Eq. 25 are either on-site or nearest neighbor interactions, except the terms in  $\sim^{e}$  and  $F_{66}$ . In contrast, all of the terms of H involve further neighbor interactions.

In a m ean eld treatm ent, it is assumed that there is a nonzero tilt present on each lattice site, even in the HTT phase

$$< R_1^2(1) + R_2^2(1) > = R^2 \in 0;$$
 (28a)

independent of 1. Then the dynam ic variable is the tilt direction,  $_1$ , with

$$R_1(I) = (1)^{i+j} R \cos_{1};$$
 (28b)

$$R_2(I) = (1)^{i+j} R \sin_{1};$$
 (28c)

with 1 = (ia; ja). Note the factor  $(1)^{i+j}$  { this is introduced because the intercell coupling must locally be antiferrodistortive, due to the corner sharing of the octahedra. By explicitly taking out this factor, it can be expected that  $_1$  will be a sm ooth function of position, with a well behaved continuum limit.

E quation 27 can be separated into intracell and intercell term s, as  $H = \frac{1}{1} (H_0^{\circ} + H_1^{\circ} + H_2^{\circ})$ , with

$$H_{0}^{\circ} = \frac{1}{2} \begin{pmatrix} 0 \\ 0 \end{pmatrix} + \begin{pmatrix} 0 \\ 2 \end{pmatrix} R^{4} + \begin{pmatrix} \frac{1}{2} \\ 2 \end{pmatrix} + \begin{pmatrix} \frac{1}{2} \\ 2 \end{pmatrix} + \begin{pmatrix} 0 \\ 2 \end{pmatrix} R^{2} \begin{pmatrix} \frac{1}{2} \\ 2 \end{pmatrix} + \begin{pmatrix} 0 \\ 2 \end{pmatrix} R^{2} \begin{pmatrix} 0 \\ 2 \end{pmatrix} + \begin{pmatrix} 0 \\ 2 \end{pmatrix} +$$

with  ${}^{0}_{0} = {}^{a}_{0} + ({}^{0}_{0} {}^{o}_{0}) = 16$  and  ${}^{0}_{2} = ({}_{2} {}^{2} {}^{0}_{0} {}^{o}_{0} {}^{o}_{0} = 4) = 8$ . Since all terms refer to the same cell, the I-dependence is not explicitly displayed. Here, H  ${}^{o}_{0}$  is -independent, H  ${}^{o}_{1}$  is a single cell H am iltonian, while H  ${}^{o}_{2}$  incorporates the intercell coupling. The intercell coupling term is complicated, and will be explicitly displayed only at the mean eld level, for which  $\cos(\mathbf{1}^{0}) = < \cos >$  and  $\sin(\mathbf{1}^{0}) = < \sin >$  for all  $\mathbf{1}^{0} \in \mathbf{1}$ . In this case, H  ${}^{o}_{2} = H {}^{0}_{2}(< \cos > ; < \sin >)$  H  ${}^{0}_{2}(0;0)$ , with

$$H_{2}^{0}(<\infty >;<\sin>) = \frac{\int_{0}^{0} \int_{0}^{0+} R^{4}}{32} (\cos + <\cos >)^{4} + (\sin + <\sin>)^{4}$$

$$-\frac{\int_{0}^{0} + 4 \int_{0}^{0}}{8} R^{4} (\cos + <\cos >)^{2} (\sin + <\sin>)^{2}$$

$$+\frac{\int_{0}^{e^{0}} R^{2}}{2} (\cos + <\cos >)^{2} + (\sin + <\sin>)^{2}$$

$$+\frac{\int_{0}^{e^{0}} R^{2}}{2} (\cos + <\cos >)^{2} (\sin + <\sin>)^{2}$$

$$+\frac{\int_{0}^{e^{0}} R^{2}}{2} (\cos + <\cos >)^{2} (\sin + <\sin>)^{2}$$

$$+\int_{0}^{e^{0}} R^{2} (\cos + <\cos >) (\sin + <\sin>)^{2} (\cos + <\cos>) (\sin + <\sin>)^{2}$$

$$+\int_{0}^{e^{0}} R^{2} (\cos + <\cos >) (\sin + <\sin>)^{2} (\cos + <\cos>) (\sin + <\sin>)^{2}$$

$$+\int_{0}^{e^{0}} R^{2} (\cos + <\cos >) (\sin + <\sin>)^{2} (\cos + <\cos>) (\sin + <\sin>)^{2}$$

$$+\int_{0}^{e^{0}} R^{2} (\cos + <\cos >) (\sin + <\sin>)^{2} (\cos + <\cos>) (\sin + <\sin>)^{2} (\cos + <\cos>) (\sin + <\sin>)^{2}$$

As discussed in [11], the terms in  $_{+}$  are non-critical, and can be eliminated from Eq. 27. Thus,  $_{+}$  (q = 0) is just the number of holes in the conduction band,  $_{+}$  (0) = 1 in the present case, where (0) (or  $_{12}$ ) becomes non-zero only in the bw-T phase, and hence can be taken as an order parameter of the transition. Thus, we may assume  $_{+}$  (q)  $_{+}$  (0), and eliminate the  $_{+}$ -dependent terms from Eq. 27. The harm onic phonon frequency is renorm alized  $!_{0}^{2} = \ddagger_{0}^{2} + \sim_{+}^{e0}(+(0) - 2)$ . In this equation, I have incorporated an additional correction [11], the term in 2, due to the lled, bonding band of the hybridized Cu-O band. This term is important in destabilizing the lattice,  $!_{0}^{2} < 0$ , both in the present problem and in ferroelectrics and other structural instabilities.

W hile the \_- -term s are neglected in the present analysis, they m ay yet have in portant e ects in these m aterials. They provide a coupling between the tilt and the local average electronic density, and lead to the possibility of a m icroscopically heterogeneous phase. Such nanoscopic disorder has previously been suggested to play an important role in doping these m aterials away from the vH s[28], while a related phase heterogeneity has been proposed to arise on doping away from the antiferrom agnetic phase at half-lling[17].

## 6b. Intracell H am iltonian: Static JT E ect

It is convenient to begin by discussing the JT e ect within a single cell. The terms in H $_0^{\circ}$  lead to a tilting of the octahedron, R  $\leftarrow$  0, but with no preferred orientation. If R is assumed to be a xed constant, then the JT e ect involves the angular orientation of the tilted octahedron, . For the single cell problem, this involves H $_1^{\circ}$ , Eq. 29b. The solution to Eq. 29b depends on whether the system is in the static or dynam ic JT lim it. In the dynam ic lim it, the tilt kinetic energy operator associated with must be added to Eq. 29b; in the opposite lim it, the tilts are static, and the kinetic energy can be neglected. In this static case, the electronic operators can be diagonalized by a transform ation sim ilar to Eq. 16. A lternatively, a pseudospin form alism [12–14,29] (Appendix IV) can be employed. In the two-dimensional subspace spanned by the electronic operators  $a_1^{\circ}$  (I),  $a_2^{\circ}$  (I), the operators can be represented by Paulim atrices

= z; 12 = x;

hence, the <sup>2</sup>-term s in Eq. 29b reduce to constants, and can be eliminated. Transform ing the electronic states by Eq. 16, the eigenenergies of Eq. 29b become

$$E_{1}^{\circ} = \frac{1}{2} \frac{0}{2} R^{4} \cos 4 \qquad \frac{1}{2} \sqrt[]{e^{02} R^{4} \cos^{2} 2} + \sqrt[]{e^{02} R^{4} \sin^{2} 2} : \qquad (30)$$

Equation 30 demonstrates the JT e ect in the present system. If  $E_1^{\circ}$  were minimized with respect to R, the electronic term would always give rise to a non-vanishing JT distortion (R  $\in$  0); incorporation of other terms from the original H am illionian of order R<sup>4</sup> would not change this result. However, since the electron-phonon coupling is quadratic in R, there are also harm onic terms in the H am illionian of order R<sup>2</sup>, and a JT splitting will arise only if the coupling coe cient (e.g.,  $e^0$ ) is large enough (or the harm onic coe cient is negative { see [11]).

Equation 30 represents a potential with four degenerate energy minima. Depending on the parameter values, these minima may lie either along the x and y axes, or at 45° to this. It is expected that  $\sim^{e0} > \sim^{e0}$ ; if  $\sim^{e0} = 0$ , the minima would lie along the principal axes when  $2 \frac{0}{2}R^2$   $j\sim^{e0}j < 0$ , and at 45° when the inequality is reversed. In the static limit, the tilted octahedron will be located at one of the four equivalent minima. In the absence of intercell coupling, there can be no macroscopic phase transition: at low tem peratures the octahedra will be random ly distributed among all four minima; as the tem perature is raised, the octahedra can hop among the various minima.

In what follows, it will be convenient to approximate the lower JT solution, E  $_1^\circ$  of Eq. 30 by a simpler form

$$E_1^{\circ} ' E_a E_b \cos 4 : \tag{31}$$

For instance, if  $\sim^{e_0} = 0$ ,  $2E_b$ ,  $j\sim^{e_0}R^2=2 + {}_{2}^{0}R^4$ . For nonzero  $\sim^{e_0}$ , the angle dependence is a function of  $\sim^{e_0} \sim^{e_0}$ . The terms which comprise  $E_b$  tend to appear as the di erence between two quantities (e.g.,  ${}_{0}^{0}$ ,  $\sim^{e_0} \sim^{e_0}$ ). This occurs because for an isolated free m olecule the VT distortions' amount to a pure rotation of the m olecule; the distortion is a solid-state e ect, due purely to crystalline anisotropy (this fact appears to have been rst pointed out in Ref. [30]). The constant  $E_a$  can be absorbed into the angle-independent part of the H am iltonian, H $_{0}^{\circ}$ .

6c. Dynam ic JT E ect and Relation to Conventional (E e) JT E ect

W hen dynamic e ects are important, the ionic kinetic energy operator from Eq. 5d must be retained in the Ham iltonian, Eq. 29b. The exact eigenstates no longer can be written in Born-Oppenheim er form, but are of the form

$$n(R;) = n1(R;) (R;) + n2(R;) + (R;)$$

where is the electronic wavefunction corresponding to the energy  $E_1^{\circ}$ , Eq. 30, and the <sub>ni</sub> are wavefunctions of the nuclear motions. In the limit of strong JT coupling, the upper JT level can be neglected, and a Born-O ppenheim er wave function is approximately recovered:

$$n = f(R)_{n}() (R;)$$

where is the lower energy electronic wave function and the nuclear wave function has been separated into a radial part, f(R), assumed to be approximately constant, and an angular part, n, which satisfies

$$\frac{h^2}{2R^2} \frac{\theta^2}{\theta_1^2} + \cos(4_1) = E_{n-n};$$
(32a)

where the rst term in Eq. 32a is the angular contribution to the tilt kinetic energy, and

$$\frac{h^2}{2R^2} = E_b:$$
(32b)

This distorted octahedron, strongly and nonlinearly coupling the tilt and the electronic state, constitutes the polaron of the present problem. For convenience, this tilt polaron will be referred to as a 'tageon'.

Equation 32a is a form of M atthieu's equation  $\beta$ 1-33] which offen arises in the dynamic JT problem. The vibronic potential here has four minima, along the positive and negative x- and y-axes (for > 0), corresponding to the four possible static JT tilts of the CuO<sub>6</sub> octahedron. When is very large, the low estenergy state is fourfold degenerate, corresponding to these static distortions, with a weak tunneling between the states. For sm aller barriers, this quartet of states breaks up into a pair of doublets. The solutions of Eq. 32a are discussed further in Appendix V.

In the closely related E e JT e ect[12-14], a sim ilar M athieu's equation arises, but with three-fold degeneracy (corresponding to elongation of the octahedron along an x, y, or z axis). This problem is often sim pli ed by approximating the intercell coupling by a quadratic form. In this case, the weak tunneling lim it reduces to a three-states Potts m odel[34,35]. For the present, four-fold degenerate m odel, this would correspond either to a pseudo-spin 3/2 system, or to a four-states Potts m odel.

# 7. Intercell C oupling

#### 7a. High-Tem perature Lim it (D isordered JT Phase)

In the intercell coupling term, < sin > and <  $\infty$ s > are independent variables, constrained by (< sin >)<sup>2</sup> + (<  $\infty$ s >)<sup>2</sup> 1. Two classes of solution are of particular interest: <  $\infty$ s > € 0, < sin > = 0, the LTT solution, and < sin > = <  $\infty$ s > € 0, the LTO solution.

The analysis is most straightforward in the weak tunneling limit, when only the four low est-lying levels of each octahedron need be considered. In the high-tem perature limit,  $< \sin > = < \cos > = 0$ , and only the single cell H am iltonian, Eq. 29a, b, need be considered. If tunneling is completely absent, the four wave functions are each localized in one of the potential minim a of cos4 . Near the minimum, the potential is quadratic in , and the wave functions are well approxim ated by harm onic oscillator wave functions. In particular, the ground state will be approxim ately a G aussian wave function,

$$=\frac{1}{2}e^{2};$$
 (33)

with  $= \frac{p}{2}$ . Inclusion of overlap between G aussians centered on di erent wells splits the degeneracy. However, just as in the 3-wellm odel, it is important to recognize that the total wave function is a combined electron-phonon wave function. The electronic wave functions are only symmetric under a 4 rotation: (+2) = (). Thus, the nuclear wave function must also satisfy

$$n(+2) = n();$$
 (34)

so that the total wave function  $_n$  has 2 symmetry. In the n= 3 case, this changes the sign of the overlap, thereby reversing the order of the levels [12,31,36]. This sign change is now recognized to be an example of Berry's phase [37].

In a perturbation calculation of the four-wellproblem, this means diagonalizing an 8 8 m atrix. However, since the wavefunctions 5-8 are just the negative of wave functions 1-4, this immediately reduces to a 4 4 m atrix 0 matrix 0 matrix

with S the wave function overlap, H $_{12}$  the nearest-neighbor H am iltonian overlap, and H $_{11}$  the diagonal H am iltonian. For the present problem, these m atrix elements are

$$H_{11} = (1 - \frac{1}{2}e^{2});$$
 (36a)

$$H_{12} = S (1 + \frac{1}{2} (e^{2} - \frac{2}{2}));$$
 (36b)

$$S = e^{2} i \frac{2}{3} i \frac{$$

with  $= h^2 = 2R^2$ . This overlap splits the four degenerate levels into two pairs of levels, with energies

$$E = \frac{H_{11}}{1} \frac{p_{\overline{2}H_{12}}}{p_{\overline{2}S}};$$
 (36d)

The wave functions associated with  $E_+$  are in the subspace spanned by the vectors  $(1=\frac{p}{2};1;1=\frac{p}{2};0)$  and  $(0;1=\frac{p}{2};1;1=\frac{p}{2})$ , where the various elements refer to the amplitudes in the separate minima, while the E wave functions correspond to  $(1=\frac{p}{2};1;1=\frac{p}{2};0)$  and  $(0;1=\frac{p}{2};1;1=\frac{p}{2})$ . These latter are higher in energy by a factor

$$E = E \qquad E_{+} = \frac{2^{\frac{p}{2}} - 2^{2} S(2^{2} + 4 + e^{2})}{1 - 2S^{2}}; \qquad (37)$$

As S ! 0, E vanishes, leading to a static, but disordered JT phase, with the octahedra equally likely to have any of the four tilt distortions. The resulting lattice sym metry is pseudo-cubic, in that all orientations are equally likely. This four well approximation becomes exact as ! 1, and Figure 3 shows that it remains qualitatively correct for all values of . The solid lines in Fig. 3 are the exact eigenvalues of Eq. 32a, as discussed in Appendix V. The axes of Fig. 3 are in normalized units, introduced in Appendix V:  $= 4 \overline{q}$ , E = 4 a.

There appears to be an asymmetry in the above wavefunctions, since they are all centered on wells 2 or 3. However, linear combinations of these wavefunctions can be generated which are centered on the other wells. For example, 2(0;1=2;1;1=2) (1=2;1;1=2;0) = (1=2;0;1=2;1).

# 7b. Phase Transitions: D ynam ic JT Phases

As the tem perature is lowered, intercell coupling will lead to an ordered low tem perature phase, with  $< \cos > or < \sin > non zero. A complete solution of Eq. 29 is prohibitively di cult, particularly since m ost of the parameters are not well known. In this section, a number of simplications are introduced to m ake the problem m ore tractable, allowing a determ ination of the conditions under which an LTO (dynamic JT) phase m ight be stable. These simplications are: (1) since a key question will be to establish whether an LTO -like phase can be stabilized in the absence of strong um klapp scattering, it will be assumed that <math display="inline">\sim^{e0} = 0$ . (2) It will be assumed that  $< \cos >$  and  $< \sin >$  are small near the transition (i.e., that the transition is second order, or weakly inst order), so that H  $_2^{\circ}$  can be linearized in these quantities.

(3) Even with these assumptions, H  $_2^\circ$  remains complicated:

$$H_{2}^{\circ} = \frac{\begin{bmatrix} 0 \\ 0 \end{bmatrix}}{8} R^{4} (\cos^{3} < \cos > + \sin^{3} < \sin >) + \begin{bmatrix} -e^{0} \\ + \end{bmatrix} R^{2} R^{2} R^{2} (\cos < \cos > + \sin < \sin >) + e^{-e^{0}} R^{2} (\cos < \cos > \sin < \sin >) + e^{-e^{0}} R^{2} (\cos < \cos > \sin < \sin >)$$

$$(38a)$$

In the same spirit of replacing Eq. 30 by Eq. 31, this may be replaced by the sim pler form

$$H_{2}^{\circ} = H_{0}^{\circ}(\cos < \cos > + \sin < \sin >);$$
(38b)

which involves only one unknown parameter,  $H_0^0$ . To see how good this approximation is, consider the case in which the tilting Hamiltonian,  $H_{tilt} = H_1^\circ + H_2^\circ$  of Eq. 29, is dominated by the vHs JT e ect (i.e. the terms involving  $\sim^{e0}$ ). In this case, the electronic term can be integrated out as in Eq. 30, leading to

$$H_{tilt} = \frac{e^{0}R^{2}}{2} (\cos + < \cos >)^{2} (\sin + < \sin >)^{2} :$$
(39)

Figure 4 shows that even for this highly singular potential, the simpler form of Eq. 31 plus 38b provides a reasonable approximation. In approximating Eq. 39, the parameter  $H_0^0$  must be chosen to be negative; hence, only this regime will be explored in detail below.

W ith the intercell coupling given by Eq. 38b, the perturbation matrix may be recalculated. The Ham iltonian matrix, Eq. 35, becomes

where  $x = H_{11}$  E,  $y = H_{12}$  SE,  $A = < \cos >$ ,  $B = < \sin >$ ,  $H_1 = H_0^0 \exp(1 = 8)$ , and  $H_2 = H_1S = \frac{p}{2}$ . For arbitrary  $< \sin > 6$  0, Eq. 39 must be diagonalized numerically. However, for the LTT phase ( $< \sin > = 0$ ), the solutions can be found analytically. The potential wells are labelled in such a way that the  $< \cos >$  terms lower the state (1;0;0;0) (state 1) and raise the state (0;0;1;0) (3) in energy. Then, in the LTT phase (B = 0), two solutions have  $_1 = 0$ , with energies

$$E_{1;2} = \frac{2SH AH_1 = 2}{1 + 2} \frac{P}{2H^2 + A^2(H_1^2 = 4 + 2H_2^2(1 + 2S^2))} \frac{2SHAH_1}{2SHAH_1};$$
 (40a)

while the other two have  $_3 = 0$  and

$$E_{3;4} = \frac{2SH + AH_1 = 2}{1 + 2S^2} \frac{P}{2H^2 + A^2} \frac{2H_1^2 = 4}{2H_2^2} \frac{2H_2^2}{(1 + 2S^2)} + \frac{2SHAH_1}{2S^2}$$
(40b)

In the above equations, E is measured from H<sub>11</sub>, and H = H<sub>11</sub>S H<sub>12</sub>. Figure 5 illustrates how the energies in the four wells vary as a function of  $\langle \cos \rangle$ , for several values of S, both for the LTT phase ( $\langle \sin \rangle \rangle = 0$  { dashed lines) and for the LTO phase ( $\langle \sin \rangle \rangle = \langle \cos \rangle \rangle$  { solid lines). Note that there is a break in slope in the LTT phase at ( $\langle \cos \rangle \rangle^2 = 1=2$ , since the constraint ( $\langle \sin \rangle \rangle^2 + (\langle \cos \rangle \rangle^2 - 1 \text{ com es}$  into play. In the gure, it is assumed that  $\langle \sin \rangle \rangle = \frac{1}{1} - (\langle \cos \rangle \rangle^2$  in this case. How ever, this regime has no immediate relevance, since  $\langle \cos \rangle \rangle$  is always found to be  $\langle 0:7$  in the numerical calculations for the LTO phase.]

From Figure 5, the energy is always lowered when  $< \cos > 6$  0, and at low enough temperatures there will be a transition to a dynamic JT phase. In mean eld theory, the phase diagram may readily be calculated from the self-consistency condition for  $< \cos > :$ 

$$<\cos > = \frac{\mathrm{T}\,\mathrm{rcos}\,\,\mathrm{e}^{\,\mathrm{H}\,\mathrm{=k_{B}}\,\mathrm{T}}}{\mathrm{T}\,\mathrm{re}^{\,\mathrm{H}\,\mathrm{=k_{B}}\,\mathrm{T}}};\tag{41}$$

where Tr stands for the trace. In the four-state model,  $\cos$  vanishes on average in wells 2 and 4, and  $\cos = e^{1=8}$  in wells 1(+) and 3({). Thus

$$< \cos > = e^{1=8} \frac{P}{e^{E_{1}=k_{B}T} + e^{E_{2}=k_{B}T} + e^{E_{3}=k_{B}T} + e^{E_{4}=k_{B}T}};$$
(42)

where  $p_{ij}$  is the probability that well i is occupied in the state of energy  $E_j$ . Note that any term common to all the  $E_i$ 's cancels out of the ratio in Eq. 42. Thus, Eq. 42 depends on three parameters, S (or, equivalently ), H, and H $_0^0$ . At su ciently high temperatures, Eq. 42 has no non-zero solutions. As T is low ered, there is

a critical tem perature below which there are values of  $< \cos > 6$  0. Figure 6 illustrates the solution for the LTT phase, plotting the right-hand side of Eq. 42 against  $< \cos >$  at a num ber of di erent tem peratures. The solutions of Eq. 42 correspond to the intersection of the solid and dashed lines. These solutions lead to the evolution of the ordered phases,  $< \cos > (T)$  shown in Figure 7.

#### 7c. Phase Transitions: LTO vs LTT Phase

Figure 7 com pares the resulting phase diagram s for both the LTT and the LTO phases, for several sets of parameters. The parameters were chosen to approximately match the critical temperature of the LTO phase in  $La_2CuO_4$ . Figure 8 shows the free energies of the two phases,

$$e^{F=k_{\rm B}T} = Tre^{H=k_{\rm B}T};$$
(43)

for the same sets of param eters.

From the above gures, it is possible to understand the competition between the LTT and LTO phases as a competition between energy and entropy. First, consider the smalloverlap case, Fig. 5a. As S ! 0, the LTO phase becomes two independent LTT type transitions, in wells 1 and 2, so two branches of the energy curve are lowered by virtually the same amount as the single branch in the LTT phase. Thus, for a xed value of  $< \cos >$ , the LTO phase has a greater entropy associated with it. However, this greater entropy in turn means that at a xed temperature, the self-consistent value of  $< \cos >$  will be smaller in the LTT phase. Eq. 41. Hence, for small S values, the LTT phase is always energetically preferred.

As S increases, however, the factor of level repulsion adds a further stabilization to the LTO phase (Fig 5b-d). The splitting of the originally degenerate pair of LTO levels drives one lower in energy than the corresponding LTT level. A lso, the mixing of di erent wells brings two LTT levels fairly close together, so the entropy di erences between the LTO and LTT phases are reduced. The result is that both phases are close in free energy over most of the tem perature range, Fig. 8, and that both phases allow non-zero solutions for < cos > out to signi cantly higher tem peratures as S increases. However, the LTO phase wins out at the higher tem peratures, and over a wider tem perature range as S gets larger { the phase diagram is illustrated in Fig. 9. O ther choices for the param eters H and H $_0^0$  would mainly shift the scales of the phase diagram, without altering its fundam ental character. Note that the LTT phase never increases its transition tem perature signi cantly above the S ! 0 lim it, whereas the LTO phase turns on at higher T's with increasing S.

W hile the above behavior is qualitatively what m ight be expected, it should be cautioned that the above calculations are perturbative in S, so the detailed nature of the large S results should be treated with caution (for instance, the LTO transition temperature appears to diverge as  $S^2$  ! 1=2). A more detailed calculation would require the inclusion of more distant overlaps in Eq. 39. However, the reduction of the M athieu problem to a four-state problem remains valid, as long as 4 is large compared to  $k_B T$ . M oreover, as F ig. 9 illustrates, for some parameter choices the LTO phase remains stable down to small S-values.

From Fig. 7, the transition from the disordered JT phase (HTT) to the LTT phase is second order, with < cos > acting as an order parameter, but the LTO ! HTT and LTO ! LTT phase transitions are rst order, with discontinuous jumps in < cos > . Note that in the LTO phase, for S 0:1, < cos > 0:4 at <u>bw tem peratures { i.e.</u>, the m acroscopic average tilt is noticeably sm aller than its instantaneous value, < cos >  $^2 + < sin > ^2$  / 0.56.

W hile the present dynam ic JT calculation has been carried out for the high- $T_c$  cuprates, it is interesting to compare it with calculations of the multiple phase transitions in the ferroelectric perovskite B at iO<sub>3</sub> [38]. There, a similar competition between energy and entropy was found, with the largest energy lowering associated with the static (rhom bohedral) JT phase, and increasingly large entropy contributions in the case of two, four, or eight potential minim a being involved in the dynam ic JT e ect. However, in the simplest calculation, all four phases had a transition at the same tem perature, so the static JT phase was stable at all tem peratures. By assuming that the interaction energy was di erent in the di erent phases, it was possible to reproduce the observed sequence of phase transitions. In the present calculation, the overlap param eter naturally provides the stabilization for the dynam ic phases, with only the static phase stable as S ! 0.

# 8a. D ynam ic JT

Figure 9 is the chief result of this paper. It con m s the suggestion [10,11] that the LTO phase can be described as a dynam ic JT phase involving a splitting of the vH s degeneracy.

The present paper has contrasted two possible origins of the LTO phase, as a static JT phase stabilized by um klapp scattering (Section 5), and as a dynam ic JT phase, Section 7c, which is naturally related to the LTT phase. By comparing the gap functions of the two models, Figs. 2 vs 7a, it can be seen that, for sm all S values, the dynam ic JT e ect can m in ic the e ect of a static transition driven by um klapp scattering, thereby con rm ing the speculation made in Paper V IIIA [10]. For larger S values, the situation is more com plicated, with the LTO transition becoming rst order.

M uch work remains to be done, particularly in simultaneously accounting for both the electronic and structural aspects of the transition, and in understanding how electronic properties are modiled within the dynamic JT phase (antiferrom agnetism, superconductivity, ...). Before this can be done, how ever, some more fundamental questions must be answered, such as, what does the Fermi surface (or even the Brillouin zone) mean in a dynamic JT system, where the local symmetry is not the same as the global symmetry, and indeed where the local symmetry can uctuate in space and time.

## 8b.SDW -CDW Competition Revisited

This paper has explored possible generalizations of CDW 's and SDW 's in the presence of a vH s. W hile the sim ple CDW can describe the LTT phase, it seems to be ruled out by a sym m etry argument in the LTO phase (Ref. [9] and Appendix III). Nevertheless, there are at least two mechanisms by which vH s-related e ects could stabilize an LTO phase. W hich of these mechanisms is actually operative in LSCO is a question which requires considerably m ore research. Nevertheless, it seems appropriate to point out that even at the molecular level, there is often a competition between JT and spin-orbit e ects[12,13], and this competition is reminiscent of the usual CDW -spin-density wave (SDW ) competition in low er-dimensional metals in the presence of a peak in the dos.

Near half lling, correlation e ects become important in destabilizing CDW -like phases. On the other hand, there has been clear experimental[39] and theoretical[40] evidence for the importance of spin-orbit coupling in the undoped materials, and speci cally in the Neel antiferrom agnetic or spiral magnetic phases. This can be understood, in the context of the present paper, as follows. To split the vH s degeneracy requires breaking the degeneracy of the two Cu's in the orthorhom bic unit cell. This can be done if they have opposite spins, but this requires spin-orbit coupling to modify the electronic bands.

I earlier suggested that the phase diagram of LSCO resembled a crossover from SDW -like behavior near half lling (the antiferrom agnetic state) to 'incipient CDW -like' behavior, including Peierls distortion, as hole doping is increased [28]. The present results suggest the following modi cation: the hole-doped LTO phase is stabilized by the dynam ic JT e ect, whereas near half lling spin-orbit e ects are more important (due to on-site Coulom b repulsion), and may stabilize a static LTO phase. This phase may be related to the proposed 'ux phase'[18]. W hereas in principle, a single spin-orbit coupled phase could persist for all dopings, there is considerable experimental evidence for a transition between two phases as a function of doping, with a (nanoscale) two-phase regime between the vH s and half lling [28].

In Section 2, it was brie y noted that c-axis dispersion acted in the same way as a CDW to split the vH s degeneracy. It would be interesting to study in m ore detail whether changes in interlayer hopping could drive a phase transition, particularly in light of Anderson's ideas that interlayer coupling plays a special role in stabilizing high-T<sub>c</sub> superconductivity [41].

### 9. Excitons' vs Cageons'

W hen I initiated this series of calculations on the vH s[42], a major premise was that inter-vH s scattering could promote large electron-phonon coupling via vH s nesting [N B. not conventional nesting], leading to short-range CDW order. Indeed, the term 'exciton' was introduced to point out that the strong scattering is associated with electron-like sections of one vH s scattering o of hole-like sections of the second vH s. The CDW order in this case would be an 'excitonic instability' analogous to the spin-density wave instability of chrom ium.

The excitonic' properties of the model were discussed in paper IV [43]; the CDW in V [27]. The present series of papers, V IIIA-C, are an extension of V: there is a structural instability, but it is not simply

describable as a CDW (the form alism of V is still relevant for extending the present m odel to a quasi-twodimensional system and incorporating m ode-m ode coupling).

Under these circum stances, the term 'excitonic' does not seem to be particularly suitable for describing the system, since the strong electron-phonon coupling will lead to excitations closer to polarons { or even solitons, as discussed below. Hence, I am introducing the term 'bageon', which is intended to better describe the JT excitations of electrons coupled to tilts of the octahedral C uO  $_6$  cages.

Going beyond the mean eld calculation, the corner sharing of the CuO<sub>6</sub> octahedra suggests that there should be long chains of LTT phase, and that defects must be introduced into the chains. A plausible model would be to have islands of LTT phase separated by LTO -like dom ain walls, which would switch an x-directed dom ain into a y-directed one. Such dom ain walls would behave as solitons, and the doping dependence of LBCO could be interpreted in terms of the generation of these solitons. Thus, at x = 0.12 (6% of the La replaced by Ba), the material is in a pure LTT phase. As x is reduced, the material transforms to the LTO phase. This transform ation could be accomplished via soliton generation { as x is decreased, the density of LTO solitons increases. The octahedral shear  $e_{12}$  would simply be proportional to the soliton density. This idea will be pursued further in a future publication.

In particular, it has been found that the degeneracy of the vH s's is split in the solitonic model. It is just this splitting which underlies the 'valence bond density wave' calculations of Ref. [10]. Hence, it seems likely that the results of that paper hold for the dynam ic JT model of the LTO phase { in particular, the phase diagram of the transitions HTT ! LTO ! superconductor should continue to hold in the dynam ic JT model.

I would like to thank J.Zak for explaining the role of the Berry phase in the JT e ect. Publication 545 from the Barnett Institute.

### Appendix I: R enorm alized M icroscopic JT B and Structure

The present analysis, in terms of  $\$ , is very convenient, but how can it be related to a microscopic H am iltonian, such as that developed in V IIIB, Appendix I? In particular, the analysis of Section 5 requires being able to de ne  $a_1^Y$  (I),  $a_2^Y$  (I) { i.e., on each atom ic site. By contrast, the microscopic H am iltonian involves interatom ic hopping between C u and O atom s. In this Appendix, I show that a site model can be derived from the microscopic H am iltonian, if the sites are not individual atom s, but clusters of atom s.

The simplest cluster is a single octahedron { or more simply, a Cu atom with the four surrounding planar O's, since the present model does not incorporate either the Cu  $d_{z^2}$  nor the apical O p orbitals. However, one octahedron is too small. There is only a single Cu-O antibonding level (twofold degenerate due to spin) per Cu atom, and hence no JT degeneracy. Hence, the appropriate cluster contains a square of four octahedra. The antibonding band' contains four levels, the middle two of which are degenerate, in the absence of strain or tilt coupling. This is a JT degeneracy, since the antibonding band' is half led (the model of V IIIB contains no O-O hopping, so the vH s falls exactly at half lling).

The dispersion of the four levels can readily be recovered from V  $\ensuremath{\text{IIIB}}$  .

$$E = \frac{E}{2}$$
  $(\frac{E}{2})^2 + 4W$ ; (I1a)

$$W = t_{c u \circ x}^{2} \left[ \cos^{2} x \sin^{2} \left( \frac{k_{x} a}{2} \right) + {}^{2} \sin^{2} x \cos^{2} \left( \frac{k_{x} a}{2} \right) \right] + t_{c u \circ y}^{2} \left[ \cos^{2} y \sin^{2} \left( \frac{k_{y} a}{2} \right) + {}^{2} \sin^{2} y \cos^{2} \left( \frac{k_{y} a}{2} \right) \right]:$$
(I1b)

Here, E is the splitting of the Cu and O levels, and  $t_{CuOx}$  ( $t_{CuOy}$ ) and x (y) are the Cu-O hopping energy and octahedral tilt along the x (y) axis, respectively. For a 'sample' two cells by two cells,  $k_x a=2$  and  $k_y a=2$ are restricted to the values 0 and =2, leading to four possible values of E, Eq. IIa, with eigenfunctions shown in Fig. 10 (top). (Strictly speaking, these are not sm all clusters, because periodic boundary conditions are assumed. Calculations on real clusters would reveal eigenstates of the sam e overall symmetry as in Fig. 10, but with modi ed eigenvalues.)

This same procedure m ay readily be generalized to larger 'samples'. For a sample N  $\sim$  N cells, there are N<sup>2</sup> levels in the antibonding band, of which N states are degenerate (when the strains and tilts are absent)

at the vH s energy level { those states for which  $k_x + k_y = -a$ . For these states, the energy can be written as Eq. 11, with

$$W = W_{a} + W_{b} \cos(k_{x}a); \qquad (I2a)$$

$$W_{a} = t_{C u0}^{2} [1 \frac{a}{r} e_{+} + \frac{4(^{2} 1)}{3m a^{2}} R^{2}];$$
 (I2b)

$$W_{b} = t_{C u0}^{2} \left[ \frac{a}{r} e + \frac{4(^{2} + 1)}{3m a^{2}} (R_{1}^{2} - R_{2}^{2}) \right];$$
(I2c)

where r ,  $R_i^2 = 3m a^2 \sin^2 i=8$ , and  $t_{Cu0i}^2 = t_{Cu0}^2 (1 2ae_{ii}=r)$ , as discussed in VIIIB (see also the last paragraph of this appendix). This equation o ers a convenient m icroscopic estimate of the electron-phonon coupling constants.

In order to nd the renormalized bands corresponding to  $_{ij}$  of Eq. 4, it is convenient to bok at how larger clusters are built up. Fig. 10 (bottom) shows the eigenfunctions associated with the 4 4 clusters. Beneath each gure, the corresponding eigenvalue is indicated in the form ij. For simplicity, this notation corresponds to the untilted clusters ( $_x = _y = 0$ ), for which W in Eq. 11b is given by  $4W = it_{CuO_X}^2 + jt_{CuO_Y}^2$ . The 4 4 eigenfunctions are built up from the 2 solutions by repeated tiling of the 4 4 cell by the 2 2 cell or its negative. Since there is no intercell mixing, the Cu-O band separates into a superposition of four overlapping but noninteracting subbands. This pattern holds for larger cells, but with som e m inor com plications: (a) all of the '+ ' Cu atom s need not have the same am plitude [exam ple: for the one-dim ensignal chain 8 cells long, the eigenfunction (+ + + + \_\_\_\_\_\_) is really (a;b;b;a; a; b; b; a), with a=b =  $\frac{1}{2}$  1]; and (b) m ost levels are degenerate in pairs, leading to eigenvalues of m ore com plicated form . These com plications do not a ect the subband separation.

From studying larger cells, a separate energy dispersion can be determined for each subband. These energy dispersions have the form of Eq.II, with a restricted range of  $k_x$ ,  $k_y$ , for each subband. Thus, for subband I (IV),  $k_x$  and  $k_y$  must both be less than (greater than) =2, while for subband II (III),  $k_x$  ( $k_y$ ) is greater, while  $k_y$  ( $k_x$ ) is less than =2. This restriction can most elegantly be carried out by introducing new articical Brillouin zone boundaries, as illustrated by the dashed lines in the inset to Fig. 11. For the case of untilted molecules, the subband dispersions are illustrated in Fig. 11. It can be seen that subbands II and III are degenerate (in the untilted case), and overlap the vHs, while band I(IV) lies below (resp. above) the vHs. For the purposes of the present calculation, bands I and IV may be neglected, while bands II and III correspond to the electronic bands discussed in the text, e.g., Eq. 4. In particular, since these bands are asymmetric in  $k_x$  vs  $k_y$ , their degeneracy will be lifted by a nonvanishing LTT-type tilt.

It should be noted that Schulz [17] has introduced a similar form alism with (spin-dependent) creation operators associated with each vH s.

ADDENDUM to Paper V IIIB [11]. In Paper V IIIB, the covalent overlap enhancem ent factor was introduced as

$$= 1 + \frac{2}{\frac{p}{3}}$$
:

Here and are related to the Slater-K oster[44] parameters of p-d overlap of or symmetry as follows: =  $V_{pd}$ , =  $V_{pd}$  (N B.,  $V_{pd}$  is negative). At the time of writing, I was unable to nd theoretical values for the two overlaps separately. Now G rant and M dM ahan [45] have provided ab initio calculations for tetragonal La<sub>2</sub>CuO<sub>4</sub> of su cient detail to allow an estimate of these parameters. Their calculations provide two estimates of . From M dM ahan and G rant, Table I:  $t(d_{x^2 \ y^2}; p) = \frac{1}{3} = 2 = 1.47eV$ ;  $t(d_{3z^2 \ r^2}; p) = = 0.50eV$ . These estimates are not exactly equal, since the wave functions are W annier functions which are not pure p and d states, due to overlap with higher orbitals. From G rant, Table 2.5  $t(d_{xy}; p) = = 0.72eV$ . A veraging the estimates, this leads to a theoretical value for ' 1:6, som ewhat sm aller than the value used in Ref. [11]. This value is in good agreement with recent cluster calculations[46]:  $V_{pd} = 1.5eV$ ,  $V_{pd} = 0.7eV$ , yielding = 1:5. I would like to thank A.M dM ahan for providing m e with copies of Ref. [45].

Appendix II: Phonon-m ediated E lectron-electron Interaction

The strain term s can be decoupled from the H am iltonian, Eq. 1, by de ning

e (q) = e (q) + 
$$\frac{G}{2C}$$
 (q) + F R<sup>(3)</sup> ( $\frac{g}{2}$ )  
2C (II1a)

$$\mathbf{e}_{12} (\mathbf{q}) = \mathbf{e}_{12} (\mathbf{q}) + \frac{2G_{66 \ 12} (\mathbf{q}) + F_{66} R_{0}^{(3)} (\frac{\mathbf{q}}{2})}{4C_{66}}$$
(II1b)

The reduced H am iltonian becomes H = H $_{str}^{0}$  + H $_{+}^{0}$  + H $_{0}^{0}$  + H $_{ph}$  + H $_{e}$ , with

$$H_{str}^{0} = C_{+} e_{+} (q)e_{+} (q) + C e (q)e_{+} (q) + 2C_{66}e_{12} (q)e_{12} (q);$$
(II2a)

$$H^{0} = \begin{pmatrix} X \\ q \end{pmatrix} R^{(3)}(\frac{q}{2}) = \begin{pmatrix} 0 \\ 0 \end{pmatrix} R^{(3)}(\frac{q}{2}) + \sim^{e0} (q) \end{pmatrix} \begin{pmatrix} X \\ \frac{J^{0}}{2} \end{pmatrix} (q) (q);$$
(II2b)

$$H_{0}^{0} = \frac{X}{q} R_{0}^{(3)}(\frac{q}{2}) \frac{\frac{0}{2}}{2} R_{0}^{(3)}(\frac{q}{2}) + \sim^{e_{0}} \frac{1}{2}(q) \qquad X = \frac{J_{0}^{0}}{2} \frac{1}{2}(q) \frac{1}{2}(q); \quad (II2c)$$

where  $_{0}^{0} = F^{2}=2C$ ,  $_{2}^{0} = F_{66}^{2}=16C_{66}$ ,  $\sim^{e0} = \sim^{e} G F = 2C$ ,  $\sim^{e0} = \sim^{e} G_{66}F_{66}=4C_{66}$ ,  $J^{0} = G^{2}=2C$ , and  $J_{0}^{0} = G_{66}^{2}=2C_{66}$ . The term H  $_{str}^{0}$  is decoupled from the remaining terms, and since it is purely quadratic, does not contain any interesting dynamics, hence can be neglected.

The form of H  $_{\rm ph}$ , Eq. 5d, does not allow a similar decoupling of the tilt term s. Such a separation can be obtained for a related 'toy' H am iltonian, which consists of Eq. 1, with H  $_{\rm ph}$  replaced by

$$H_{ph}^{T} = \frac{!^{20}}{2} R_{+}^{(3)}(0) + \frac{1}{2} X_{q}^{(3)}(\frac{q}{2}) R_{+}^{(3)}(\frac{q}{2}) R_{+}^{(3)}(\frac{q}{2}) + R_{+}^{(3)}(\frac{q}{2}) R_{-}^{(3)}(\frac{q}{2}) + \frac{2}{2} R_{0}^{(3)}(\frac{q}{2}) R_{0}^{(3)}(\frac{q}{2}) + \frac{2}{2} R_{0}^{(3)}(\frac{q}{2}) R_{0}^{(3)}(\frac{q}{2}) + \frac{2}{2} R_{0}^{(3)}(\frac{q}{2}) R_{-}^{(3)}(\frac{q}{2}) + \frac{2}{2} R_{0}^{(3)}(\frac{q}{2}) + \frac{2}{2} R_{0}^{(3)}(\frac{q$$

If  ${}^{\circ}_{0} = ({}_{0} + {}^{a}_{0})=16$ ,  ${}^{\circ}_{2} = {}_{2}=16$ , and  $!^{20} = {}^{12}(q_{R})$ , then Eq. II3 will be identical to Eq. 5d for the soft mode, q = 0,  $q^{0} = q_{R}$  (=a;0) or (0; =a). Equation II3 can now be incorporated into Eqs. II2b, c by substituting  ${}^{0}_{0} = ! {}^{0}_{0}$   ${}^{\circ}_{0} + {}^{0}_{0}$  and  ${}^{0}_{2} ! {}^{0}_{2}$   ${}^{\circ}_{2} + {}^{0}_{2}$  into the latter equations, and replacing H  ${}^{T}_{ph}$ , with

$$H_{ph}^{0} = !^{20} R_{+}^{(3)} (0):$$
 (II3b)

At this point, the tilt couplings can be form ally decoupled from the toy H am iltonian by a procedure sim ilar to the strain decoupling, by de ning

$$\mathbb{R}^{(3)}\left(\frac{q}{2}\right) = \mathbb{R}^{(3)}\left(\frac{q}{2}\right) + \frac{\sim^{e_0}}{2 \ 0} \left(\frac{q}{2}\right);$$
 (II4a)

$$\mathbb{R}_{0}^{(3)}\left(\frac{q}{2}\right) = \mathbb{R}_{0}^{(3)}\left(\frac{q}{2}\right) + \frac{2^{-e^{0}}}{\frac{1}{2}}\left(\frac{q}{2}\right) = \mathbb{R}_{0}^{(3)}\left(\frac{q}{2}\right) = \mathbb{R}_{0}^{(3)}\left(\frac{q}{2}\right) + \frac{2^{-e^{0}}}{\frac{1}{2}}\left(\frac{q}{2}\right) = \mathbb{R}_{0}^{(3)}\left(\frac{q}{2}\right) = \mathbb{R}_{0}^{(3)}\left(\frac{q}{2}\right) + \mathbb{R}_{0}^{(3)}\left(\frac{q}{2}\right) = \mathbb{R}_{0}^{(3)}\left(\frac{q}$$

In this case,  $H = H_{str}^{0} + H_{R} + H$ , with

$$H_{R} = !^{20} \mathcal{R}_{+}^{(3)}(0) + \begin{pmatrix} X & X \\ 0 & 0 \end{bmatrix} \left[ \begin{array}{c} 0 & \mathcal{R}_{1}^{2} \\ 0 & 0 \end{bmatrix} \mathcal{R}_{1}^{2} \left( \frac{q}{2} \right) \mathcal{R}_{1}^{2} \left( \frac{q}{2} \right) \right] + \frac{0}{2} \mathcal{R}_{0}^{2} \left( \frac{q}{2} \right) \mathcal{R}_{0}^{2} \left( \frac{q}{2} \right) \mathcal{R}_{0}^{2} \left( \frac{q}{2} \right)$$
(II5a)

$$H = \begin{pmatrix} X \\ q \end{pmatrix} = \frac{J_{+}}{2} + (q)_{+} (q)_{+} (q)_{+} + \frac{J_{-}}{2} (q)_{-} (q)_{-} + \frac{J_{0}}{2}_{-} (q)_{-} (q)_{-$$

with

$$J = \frac{G^2}{2C} + \frac{2}{2} \frac{0}{0} \frac{1}{0}$$
(II6a)

$$J_0 = \frac{G_{66}^2}{2C_{66}} + \frac{4^{-e^{02}}}{\frac{0}{2}}:$$
 (II6b)

Even for the toy model, this separation must be treated with caution, because of the unusual form of the substitution, Eq. II4. In the strain case, the separation can be carried out by a canonical transformation, whereas in the present problem, this does not seem to be the case, due to the quadratic term in R in Eq. II4.

## Appendix III: Structural Instabilities in the Uniform LTO Phase

This Appendix analyzes the question of whether a uniform LTO phase could be brought about by electron-phonon interaction. That is, can the large dos associated with the vH s's be driven below the Ferm i level by a lattice distortion. It has been shown that the LTO transition does not split the degeneracy of the vH s's[9], but in itself, this is not su cient. There are two alternative means by which the dos could be shifted below the Ferm i level, without splitting the vH s degeneracy. Here it is shown that neither of these e ects arises in LSCO, in the absence of spin-orbit interaction.

These e ects are: (1) there is a single peak in the dos, due to both (degenerate) vH s's, but the structural transition shifts this peak below the Ferm i level; or (2) um klapp scattering couples two vH s's opening a gap in the dos, as discussed in Section 5. Case (1), which will be discussed in Section IIIa, would arise if, for example, due to the orthorhom bic distortion, the vH s's no longer occured at the corners of the orthorhom bic B rillouin zone, or if the transition reduced the magnitude of the average 0 -0 hopping matrix element.

## IIIa: O rthorhom bic D istortion

The Brillouin zone of Fig. 1b for the LTO phase has been oversimplied by the neglect of the orthorhom – bic splitting. The LTO phase modiles the Brillouin zone of the HTT tetragonal phase in two ways. First, the principal axes a and b are rotated by  $45^{\circ}$  with respect to the tetragonal axes, a and b, Fig. 1b. (The real space cell is doubled in area, so the Brillouin zone is halved.) Secondly, there is a sm all orthorhom bic distortion, a f b, which was neglected in Fig. 1b.

This distortion can readily be incorporated into the tight-binding calculations of Appendix I. When these calculations are repeated for the larger LTO unit cell, two changes arise. First, each band becomes two-fold degenerate (due to the two Cu's per unit cell). Secondly, in all dispersion relations, such as Eqs. II, I2, the following substitutions must be made:

$$k_x a ! \frac{+}{2};$$
 (III1a)

$$k_y a ! \frac{+}{2};$$
 (III1b)

with  $_{+} = k_{+}a$ , = k b, and k the wave vectors along the new principal axes. As a result of this transform ation, the topology of the Ferm i surfaces is maintained as the Brillouin zone is stretched into a rectangle. In particular, the vH s's continue to intersect the Brillouin zone boundaries in the corners of the zone, as in Fig. 1b. Thus, the orthorhom bic distortion does not alter the ratio of the area of a given Ferm i surface to the total Brillouin zone area { and hence does not change the doping at which the vH s's coincide with the Ferm i level.

This still does not rule out the possibility of a shift of the vH s away from the Ferm i level. Thus, the doping  $x = x_c$  at which the vH s coincides with the Ferm i surface is controlled by the curvature of the Ferm i surface at the vH s. The ratio of the area of the hole Ferm i surface to the total B rillouin zone area is  $(1 + x_c)=2$ . But the curvature of the Ferm i surface is proportional to the 0-0 hopping parameter,  $t_{00}$ : when  $t_{00} = 0$ , the Ferm i surface is square. Since the orthorhom bic distortion changes all 0-0 distances (and produces two inequivalent distances), it could lead to a change in the average value of  $t_{00}$ , and hence a shift of  $x_c$ . Such an elect is likely to be small, since one 0-0 separation increases while the other decreases, so the corresponding changes in  $t_{00}$  tend to cancel.

and

#### IIIb: Um klapp Scattering and G roup Theory

The role of um klapp scattering can best be appreciated by analyzing a Ferm i surface away from the vHs, on the side of overdoping, Fig. 12a. Simple zone folding from the tetragonal to the orthorhom bic B rillouin zone produces the lens-shaped orbits shown in Fig. 12a. However, these orbits are anom alous, having discontinuous slopes at the B rillouin zone boundary. In most band structures, um klapp scattering causes an interaction between carriers from opposite sides of the B rillouin zone, opening a gap between successive bands. This causes the Ferm i surfaces of each band to intersect the B rillouin zone boundaries orthogonally, so that in crossing the zone boundary (in an extended-zone scheme) the carrier stays within the same band, and there is no slope discontinuity.

Such an interaction will arise in a tight-binding m odel in the following fashion. The orthorhom bic unit cell contains twice as many atoms as the original tetragonal cell. This will double the size of the energy eigenvalue matrix, and the num ber of bands, having the bands degenerate in pairs. To split the degeneracy of the bands requires that the matrix elements of form erly equivalent atoms (e.g., the two Cu atoms in the cell) be di erent. However, there is a (glide) symmetry operation which can translate one Cu into the other, so the matrix elements can only di er in overall sign { e.g., terms proportional to sin , in Appendix I. Since these terms enter the eigenvalue equation only in the square, they cannot produce an energy splitting. Thus, um klapp coupling is absent {  $_{12}=0$ .

But how can the slope discontinuities of the lens orbits be accounted for? This can best be understood by a general symmetry argument, based on the Bm ab space group of the LTO phase. There is a glide plane perpendicular to the b direction, which interchages the two Cu atoms in a cell. Because of this, all eigenfunctions on the a -face of the Brillouin zone must be doubly degenerate [47]. In the presence of such degeneracy, the slope of the E (k) curves can be discontinuous. Such a situation always arises in the presence of glide planes, and is perhaps best known for the hexagonal close packed space group [48]. In this case, one zone boundary does not introduce a gap, and the E (k) curve from the rst band merges continuously into the second band on crossing the zone boundary. It is often convenient to ignore the zone boundary, and work with a larger k-space zone [49]. Such a double zone for the LTO phase is illustrated in Fig. 12b: the zone is doubled in the X direction (along a ), while a gap is allowed along the Y direction. Thus, lens orbits appear only along the zone face at Y , with open orbits along X [50].

### IIIc: Spin-O rbit Interaction

Spin-orbit coupling lifts most of these degeneracies, so that the enlarged k-space zone can no longer be used [51]. The Bm ab space group is equivalent to the Cm ca space group, which includes the structure of the elements Br, I, and Ga. The group theoretical analysis for Ga has been carried out by Koster [52], who nds that spin-orbit coupling elim inates most of the degeneracy on the faces of the Brillouin zone. This is illustrated in Fig. 13. A complication arises in that the orthorhom bic unit cell, with axes a , b , and c is not prim itive. Figure 13a shows this cell, with the prim itive cell (containing only half as many atom s) inscribed in it. The Figure also shows the Brillouin zones corresponding to the primitive cell (Fig. 13b) and the orthorhom bic cell (Fig. 13c) { for convenience, the latter zone will be called the pseudozone. Its im portance arises because it is the natural zone for tight-binding m odel calculations, particularly in the two-dimensional lim it when the energy bands are assumed independent of  $k_z$ . Figure 13 illustrates how the true zone may be folded into the pseudozone. Figure 13b shows the rst pseudozone inscribed in the full zone, while Fig. 13d shows how the second pseudozone is reassembled from the leftover parts of the full zone. This folding produces two bands, which are degenerate within a tightbinding calculation such as that of Appendix I. Note the relative orientation of the two pseudozones in the full zone: the second zone is predom inantly displaced from the st by the Q-vector  $\tilde{z} = \tilde{z} = 2$ . This is because the unit cell (Fig. 13a) includes contributions from two CuO<sub>2</sub> planes displaced along the c-axis, which are equivalent in the tight-binding scheme.

By including additional terms in the tight-binding calculation, it is in principle possible to couple the two bands and remove the twofold degeneracy. However, a group theoretical analysis shows that not all of the degeneracy can be lifted. In Figs. 13b,c, the hatched areas show the regions in the Brillouin zone (all con ned to the surface of the zone) in which the wave functions are two-fold degenerate (neglecting spin degeneracy) in the absence of spin-orbit coupling: this happens throughout the L X N plane and along

the line M N.W hen spin-orbit coupling is included, the degeneracy is lifted except on the regions which are heavily shaded: along the X L line and at the M point.

From the pseudozone of Fig. 13c, the approximate two-dimensional Brillouin zone (Figs. 1b, 12a) is found by neglecting the band dispersion along the c-axis, which should be a good approximation for the cuprates. From Figure 12, it can be seen that spin-orbit coupling lifts the degeneracy over must of the Brillouin zone boundary. In particular, the lens orbits will be continuous at the zone boundary, due to the opening of a gap, and spin-orbit coupling can lead to an um klapp gap even at the vH s, thereby stabilizing a uniform LTO phase, as discussed in Section 5.

#### Appendix IV . P seudospin Form alism

The calculations of Sections 6b, c are similar to previous studies of structural phase transitions [12–14,29], which have introduced pseudospin form alism s, to describe either the electronic or the phonon m odes. These form alism s are offen based on an imperfect analogy, but are valuable because spin system s are understood so m uch better than nonlinear phonon system s. To clarify comparison with these works, the form alism is discussed in this Appendix. The pseudospin form alism applies to the order-disorder limit of structural phase transitions. That is, it is assumed that at each lattice site the system is disordered into one of two (or m ore) possible con gurations. In the present problem, an electronic pseudospin can be introduced, with the 'up' spin associated with occupancy of the  $_{11}$  vH s, and the 'down' spin with  $_{22}$  electrons. Then

$$z_{i} = a_{1i}^{y} a_{1i} \quad a_{2i}^{y} a_{2i};$$
 (IV 1a)

$$x_{i} = a_{1i}^{y} a_{2i} + a_{2i}^{y} a_{1i};$$
 (IV 1b)

$$y_i = i(a_{2i}^y a_{1i} \quad a_{1i}^y a_{2i});$$
 (IV 1c)

where the subscript i labels the atom ic site. The spin operators satisfy the commutation relations

$$[_{il}; _{jm}] = 2i_{ijk} _{lm} _{kl}:$$
 (IV 2)

The operators can then be rew ritten in term s of pseudospins. In particular,

$$(0) = \begin{bmatrix} X \\ a_{1k}^{y} a_{1k} \\ a_{2k}^{y} a_{2k} \\ i \end{bmatrix} = \begin{bmatrix} X \\ z_{1} \\ z_{2} \end{bmatrix} S_{z};$$
(IV 3a)

$$(\mathbf{q}) = \sum_{z i}^{\mathbf{k}} \mathbf{e}^{i\mathbf{q}} \mathbf{F} \mathbf{S}_{z} (\mathbf{q}):$$
(IV 3b)

Thus, condensation into the LTT phase corresponds to a pseudospin ferrom agnetic transition within the plane,  $< S_z > 6$  0; the overall tetragonal sym m etry arises because the interlayer coupling is antiferrom agnetic.

In the present model, the pseudospins are again only of approximate validity. The problem lies in the term  $_{ik} E_k a_{ik}^y a_{ik}$ . In an order-disorder model, each electronic state would have to be either in state 1, associated with the X-point vH s, or state 2, associated with the Y-point vH s, in which case  $a_{1k}^y a_{1k} + a_{2k}^y a_{2k} = 1$  for each k-value. In fact, while the dos peaks are split, there remains a signi cant overlap of the two bands, and for these states, the sum can reach a value 2. Hence, the  $E_k$ -term must be retained in Eq. 19a, leading to a very di erent form of gap equation from a pseudospin calculation.

# Appendix V: Solutions of M athieu's Equation (Eq. 32a)

The solutions of Eq. 32a can be written in the form of a Fourier series [31]

$$= \begin{array}{c} X^{i} \\ a_{m} e^{im} ; \\ m = 1 \end{array}$$
 (V1)

where the boundary conditions require that m + 1=2 is an integer. Substituting V1 into Eq. 32a yields the recursion relation

$$a_{m} (E_{m} m^{2}) + \frac{1}{2} (a_{m} 4 + a_{m+4}) = 0;$$
 (V2)

where  $E_m$  is the eigenvalue and  $= h^2 = 2R^2$ . Eq. V2 only m ixes m-values separated by 4, so there are four families of solution, depending on whether the series V1 contains term s with m equal to 3/2, 1/2, -1/2, or -3/2. Since the recursion relation contains only m<sup>2</sup>, these terms are degenerate in pairs for any value of . When = 0, each term in V1 is an exact solution, with eigenvalue  $E_m = m^2$ . Nonzero leads to mixing of these states, and for large , each level is fourfold degenerate (corresponding to independent oscillations about one of the four potential m inim a).

In nding the eigenvalues of Eq. 32a, it is convenient to generalize the equation to:

$$\frac{d^2y}{dz^{02}} + (a^0 \quad 2q^0 \cos(lz^0))y = 0;$$
 (V 3)

where the number of m inim a, l, is arbitrary, and the boundary condition is that  $y(z^0 + 1) = y(z^0)$ . This agrees with Eq. 32a when  $a^0 = E_n = , q^0 = = 2, z^0 = ,$  and l = 4. In turn, Eq. V3 can be reduced to the canonical form of a M athieu function of fractional order[33] by the substitution  $z = lz^0=2$ ,  $a = 4a^0=l^2$ ,  $q = 4q^0=l^2$ , so

$$\frac{d^2y}{dz^2}$$
 + (a 2qcos(2z))y = 0: (V 4)

From the boundary condition, the solution can be written in the form of series V1, with m = n + p = 1, where n is an arbitrary integer and p is an odd integer l. These solutions are the fractional M athieu functions of order p=1, and the eigenvalues can be read o of Fig. 11 of M cLachlan [33] (p. 98). For xed n, there are l solutions lying between the solutions of the integral M athieu functions, of orders n and n + 1 (actually, in the Stable' zone between the solutions  $a_n$  and  $b_{n+1}$ ) { see Fig. 14 for l = 3;4;5. For even l, the solutions are all doubly degenerate, while for odd l, there is an additional singly degenerate level w henever p = l. As l increases, the allowed states llthe Stable' intervals of M athieu's equation, with gaps between successive n values, m uch as the band structure of a one-dimensionalm etal lls in as more and m ore atom s are added to the chain.

Specializing now to the case of interest, l = 4, the eigenvalues are shown in Fig. 14, constructed by interpolation from M cLachlan's Fig. 11. The nature of the eigenstates can be appreciated by going to the  $q = 0 \lim \pm 1$ . In this case, the eigenstates are  $y_{pc} = \cos (p = 2)$  or  $y_{ps} = \sin (p = 2)$ , with p = 1; 3. Thus,  $y_{pc}^2 = 1$ , 0.5, 0, or 0.5 in the wells 1, 2, 3, and 4, for either value of p. The di erence is that  $y_{3c}$  has additional maxim a outside of the potential minima. The functions  $y_{ps}$  are similar, with wells 1 and 3 interchanged. Since  $y_{1c}$  and  $y_{1s}$  are degenerate, a number of alternative solutions can be constructed, including ones centered on wells 2 or 4. As q increases, the interwell tunneling probability decreases, and for su ciently large barriers, the wave functions should localize within a single well. It might be anticipated that the individual wave functions would narrow, causing the overlap of wave functions between wells to decrease. A plausible measure of this decrease would be  $p = y_{pc}^2 (2) = y_{pc}^2 (1)$  { i.e., the overlap probability of the wave function being found at the center of well 2 given that its peak value is centered in a neighboring well, 1. Surprisingly, p = 0.5, independent of q. Localization arises from the mixing of the p = 3 states into the p = 1 states, so that the gap E between these two levels can be taken as a delocalization energy.

The eigenvalues may be found more precisely (Fig. 3) by deriving a continued-fraction eigenvalue equation. Letting  $v_{np} = a_m = a_m - 4$ , with m = (p + 8n)=2, Eq. V2 can be rewritten

$$v_{np} = \frac{q}{a (p+8n)^2 q v_{n+1,p}}$$
: (V 5)

Here p is a positive integer which labels the four series, p = 1;3;5;7. Equation V 5 is readily solved as a continued fraction

$$v_{np} = \frac{q}{a [p+8n]^2} \frac{q^2}{a [p+8(n+1)]^2 \frac{q^2}{a [p+8(n+2)]^2 \dots}};$$
 (V 6)

Equations V2 and consequently V6 hold for n 1, but the equation for n = 0 is more complicated, since it mixes the series for p and p 8 p. This equation can be written in the form

$$v_{1p} = \frac{a \quad q \quad p^2}{q};$$
 (V 7a)

$$v_{1p} = \frac{a \quad q = \quad p^2}{q};$$
 (V 7b)

with  $= a_{p=2}=a_{p=2}$ . Equating the right-hand side of Eq. 6, for n = 1, to the right-hand side of Eq. 7 gives the eigenvalue equation for the M athieu function { actually a pair of equations for  $v_{1p}$  and  $v_{1p}$ . The quantity can be found by subtracting the two equations. Letting

$$y = \frac{p^{2} p^{2} + q(v_{1p} v_{1p})}{2q};$$
$$= y \frac{p}{1 + y^{2}}:$$

then

The two possible values give the two degenerate eigenstates for each energy. Substituting either into Eq. V 7a yields a single eigenvalue equation for a (q), which is solved num erically to generate Fig. 3.

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# Figure Captions

Fig.1 Ferm isurfaces at vHs associated with (a) LTT phase; (b) LTO phase.

- Fig.2 LTO phase diagram based on strong um klapp scattering (Eq. 22). Solid lines correspond to  $J_0 = 200$ , 300, 400, or 500K, in order of increasing gap, D.
- Fig. 3 Lowest energy eigenvalues of M athieu's equation, Eq. 32a. Both the exact solutions (solid lines) and the approximate solutions of Eq. 36d ( $E_+$  = dashed line; E = dotted line) are shown.
- Fig. 4 Solid lines = potential well of Eq. 39,  $\hat{E} = 2H_{tilt} = e^{e\theta}R^2$ , with  $< \cos > = 0.2$ , for (a) LTT and (b) LTO phases. D ashed lines are approximations to the potential using Eqs. 31 + 38b.
- Fig. 5 Eigenfunctions of Eq. 39 for the LTT (dashed lines) and LTO phases (solid lines), assuming H = 400K,  $H_0^0 = -200K$ , for several values of the overlap S = 0.001 (a), 0.01 (b), 0.1 (c), and 0.5 (d).
- Fig. 6 G raphical solution of Eq. 42, where A rg is the right hand side of Eq. 42 (solid lines) and the dashed line is  $< \cos >$ . The solution of Eq. 42 is at the point where solid and dashed lines intersect (led circles). The calculations assume the same parameters as Fig. 5, with S = 0.01, and the various solid lines correspond to T = 100, 80, 60, 40, or 20K, in order of increasing  $< \cos >$ .
- Fig. 7 Equilibrium values of  $< \cos >$  (solutions of Eq. 42) for the LTT (dashed lines) and LTO phases (solid lines). The parameters of Eq. 42 were chosen as H = 400K,  $H_0^0 = -200K$ , with variable S. In order of decreasing values of  $< \cos >$  or  $T_c$ , the values of S in part (a) are 0.0001, 0.01, 0.02, 0.05, and 0.1. In part (b), the values of S are, in order of increasing  $T_c$ , 0.3, 0.4, 0.48, 0.5, 0.52, and 0.55. The transition temperature  $T_c$  has a minimum around S ' 0.2.
- Fig. 8 Free energies of LTT (dashed lines) and LTO phases (solid lines), for the same parameters as in Fig. 7. Increasing S corresponds to increasing magnitude of F in part (a), but decreasing magnitude of F in part (b). Filled circles in part (b) show LTO-LTT crossover.
- Fig. 9 Phase diagram of dynamic JT transitions. Solid lines show HTT! LTO and LTO! LTT phase boundaries,  $T_c$  (S), for the same parameters as Figs. 5-8: H = 400K,  $H_0^0 = 200K$ . Dashed lines are for the alternative parameters H = 600K,  $H_0^0 = 900K$ .
- Fig. 10 Eigenfunctions of Eq. 11, for 2 2 (top) and 4 4 (bottom) clusters. In each cluster, only the Cu's are indicated. The -sign corresponds to the relative phase of the Cu  $d_{x^2} = y^2$  orbitals (periodic boundary conditions assumed).
- Fig. 11 Partial densities of states for the four subbands corresponding to Fig. 10a (dashed lines) along with the total dos (solid lines). Inset: Brillouin zone showing subband boundaries.
- Fig.12 Ferm i surfaces of LTO phase, with orthorhom bic distortion: (a) ordinary cell, including spin-orbit coupling. C incles on zone boundary show points where bands must be degenerate, lled circle in plies degeneracy for all points along k<sub>z</sub>, open circle in plies degeneracy for special points only. (b) D ouble zone appropriate when spin-orbit coupling is absent.
- Fig. 13 G roup theoretical analysis of orthorhom bic B rillouin zone. (a) R eal space cell of orthorhom bic phase, show ing orthorhom bic cell (long dashed lines) and inscribed prim itive cell (short dashed lines). D otted lines = glide planes. The open and lled circles represent C u atom s, with lled circles representing

atom s at x = 0; a , and open circles atom s at x = a = 2. The solid lines represent the canted planes of the 'planar' O's. (b) Full Brillouin zone, corresponding to primitive cell. D ashed lines = inscribed pseudocell. Light shading represents portions of Brillouin zone surface where the bands are twofold degenerate in the absence of spin-orbit coupling (i.e., the X L N face and the line N M). Heavy shading indicates those portions where the degeneracy persists in the presence of spin-orbit coupling (the line L X and the point M). (c) Orthorhom bic pseudozone. Shading has same meaning as in Fig. 13b. (d) Zone folding construction of second pseudozone. Here shading illustrates how sections are folded from the full zone into the pseudozone.

Fig. 14 Eigenvalues of fractional Mathieu's function. Solid lines = solutions to the integral Mathieu's function and boundaries of stability for the fractional values. Fractional solutions are shown for orders 1/3 (short dashed lines), 1/4 (long dashed lines), and 1/5 (dotted lines). [A fler R ef. [33].]